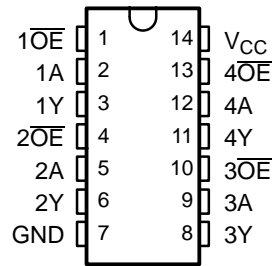


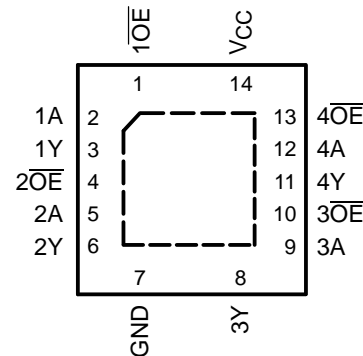
FEATURES

- Operates From 1.65 V to 3.6 V
- Specified From -40°C to 85°C and -40°C to 125°C
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 4.8 ns at 3.3 V
- Typical V_{OLP} (Output Ground Bounce) $<0.8\text{ V}$ at $V_{CC} = 3.3\text{ V}$, $T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) $>2\text{ V}$ at $V_{CC} = 3.3\text{ V}$, $T_A = 25^{\circ}\text{C}$
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

D, DB, NS, OR PW PACKAGE
(TOP VIEW)



RGY PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

This quadruple bus buffer gate is designed for 1.65-V to 3.6-V V_{CC} operation.

The SN74LVC125A features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable (\overline{OE}) input is high.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

ORDERING INFORMATION

T_A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RGY	Reel of 1000	SN74LVC125ARGYR	LC125A
-40°C to 125°C	SOIC – D	Tube of 50	SN74LVC125AD	LVC125A
		Reel of 2500	SN74LVC125ADR	
		Reel of 250	SN74LVC125ADT	
	SOP – NS	Reel of 2000	SN74LVC125ANSR	LVC125A
	SSOP – DB	Reel of 2000	SN74LVC125ADBR	LC125A
	TSSOP – PW	Tube of 90	SN74LVC125APW	LC125A
Reel of 2000		SN74LVC125APWR		
Reel of 250		SN74LVC125APWT		

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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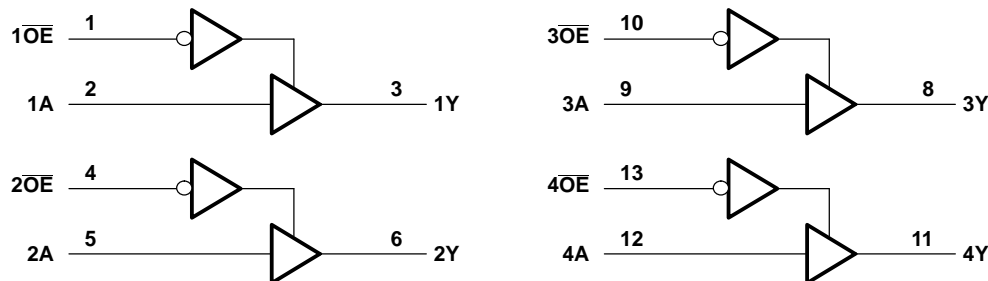
SN74LVC125A QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

SCAS2900–JANUARY 1993–REVISED AUGUST 2005

**FUNCTION TABLE
(EACH BUFFER)**

INPUTS		OUTPUT Y
\overline{OE}	A	
L	H	H
L	L	L
H	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	6.5	V
V_I	Input voltage range ⁽²⁾	-0.5	6.5	V
V_O	Output voltage range ⁽²⁾⁽³⁾	-0.5	$V_{CC} + 0.5$	V
I_{IK}	Input clamp current		-50	$V_I < 0$ mA
I_{OK}	Output clamp current		-50	$V_O < 0$ mA
I_O	Continuous output current		±50	mA
	Continuous current through V_{CC} or GND		±100	mA
θ_{JA}	Package thermal impedance		86	°C/W
		D package ⁽⁴⁾		
		DB package ⁽⁴⁾	96	
		NS package ⁽⁴⁾	76	
		PW package ⁽⁴⁾	113	
	RGY package ⁽⁵⁾	47		
T_{stg}	Storage temperature range	-65	150	°C
P_{tot}	Power dissipation		500	$T_A = -40^\circ\text{C to } 125^\circ\text{C}^{(6)(7)}$ mW

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.
- (5) The package thermal impedance is calculated in accordance with JESD 51-5.
- (6) For the D package: above 70°C, the value of P_{tot} derates linearly with 8 mW/K.
- (7) For the DB, NS, and PW packages: above 60°C, the value of P_{tot} derates linearly with 5.5 mW/K.

Recommended Operating Conditions⁽¹⁾

			T _A = 25°C		–40°C to 85°C		–40°C to 125°C		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage	Operating	1.65	3.6	1.65	3.6	1.65	3.6	V
		Data retention only	1.5		1.5		1.5		
V _{IH}	High-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}		0.65 × V _{CC}		0.65 × V _{CC}		V
		V _{CC} = 2.3 V to 2.7 V	1.7		1.7		1.7		
		V _{CC} = 2.7 V to 3.6 V	2		2		2		
V _{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.35 × V _{CC}		0.35 × V _{CC}		0.35 × V _{CC}		V
		V _{CC} = 2.3 V to 2.7 V	0.7		0.7		0.7		
		V _{CC} = 2.7 V to 3.6 V	0.8		0.8		0.8		
V _I	Input voltage	0	5.5	0	5.5	0	5.5	V	
V _O	Output voltage	0	V _{CC}	0	V _{CC}	0	V _{CC}	V	
I _{OH}	High-level output current	V _{CC} = 1.65 V	–4		–4		–4		mA
		V _{CC} = 2.3 V	–8		–8		–8		
		V _{CC} = 2.7 V	–12		–12		–12		
		V _{CC} = 3 V	–24		–24		–24		
I _{OL}	Low-level output current	V _{CC} = 1.65 V	4		4		4		mA
		V _{CC} = 2.3 V	8		8		8		
		V _{CC} = 2.7 V	12		12		12		
		V _{CC} = 3 V	24		24		24		
Δt/Δv	Input transition rise or fall rate	8		8		8		ns/V	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	T _A = 25°C			–40°C to 85°C		–40°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V _{OH}	I _{OH} = –100 μA	1.65 V to 3.6 V	V _{CC} – 0.2			V _{CC} – 0.2		V _{CC} – 0.3		V
	I _{OH} = –4 mA	1.65 V	1.29			1.2		1.05		
	I _{OH} = –8 mA	2.3 V	1.9			1.7		1.55		
	I _{OH} = –12 mA	2.7 V	2.2			2.2		2.05		
	I _{OH} = –24 mA	3 V	2.4			2.4		2.25		
V _{OL}	I _{OL} = 100 μA	1.65 V to 3.6 V	0.1			0.2		0.3		V
	I _{OL} = 4 mA	1.65 V	0.24			0.45		0.6		
	I _{OL} = 8 mA	2.3 V	0.3			0.7		0.75		
	I _{OL} = 12 mA	2.7 V	0.4			0.4		0.6		
	I _{OL} = 24 mA	3 V	0.55			0.55		0.8		
I _I	V _I = 5.5 V or GND	3.6 V	±1			±5		±20		μA
I _{OZ}	V _O = V _{CC} or GND	3.6 V	±1			±10		±20		μA
I _{CC}	V _I = V _{CC} or GND, I _O = 0	3.6 V	1			10		40		μA
ΔI _{CC}	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	2.7 V to 3.6 V	500			500		5000		μA
C _i	V _I = V _{CC} or GND	3.3 V	5							pF

SN74LVC125A

QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

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Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

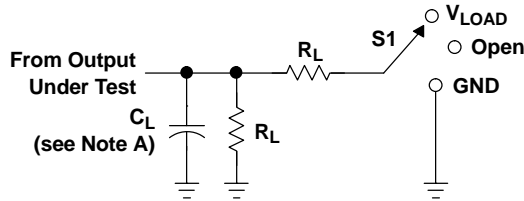
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	T _A = 25°C			–40°C to 85°C		–40°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Y	1.8 V ± 0.15 V	1	4.5	11.8	1	12.3	1	13.8	ns
			2.5 V ± 0.2 V	1	2.7	5.8	1	6.3	1	8.4	
			2.7 V	1	3	5.3	1	5.5	1	7	
			3.3 V ± 0.3 V	1	2.5	4.6	1	4.8	1	6	
t _{en}	\overline{OE}	Y	1.8 V ± 0.15 V	1	4.3	13.8	1	14.3	1	15.8	ns
			2.5 V ± 0.2 V	1	2.7	6.9	1	7.4	1	9.5	
			2.7 V	1	3.3	6.4	1	6.6	1	8.5	
			3.3 V ± 0.3 V	1	2.4	5.2	1	5.4	1	7	
t _{dis}	\overline{OE}	Y	1.8 V ± 0.15 V	1	4.3	10.6	1	11.1	1	12.6	ns
			2.5 V ± 0.2 V	1	2.2	5.1	1	5.6	1	7.7	
			2.7 V	1	2.5	4.8	1	5	1	6.5	
			3.3 V ± 0.3 V	1	2.4	4.4	1	4.6	1	6	
t _{sk(o)}			3.3 V ± 0.3 V					1		1.5	ns

Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V _{CC}	TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	f = 10 MHz	1.8 V	7.4	pF
			2.5 V	11.3	
			3.3 V	15	

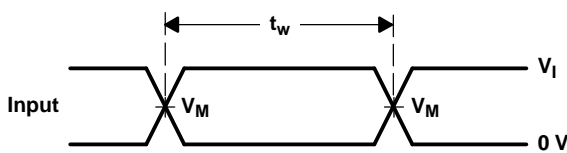
PARAMETER MEASUREMENT INFORMATION



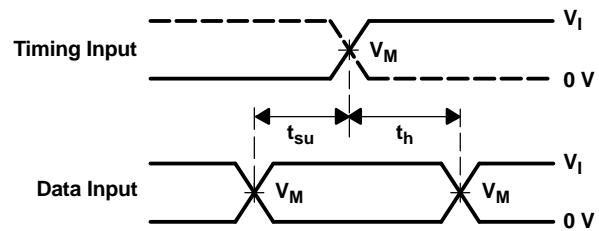
LOAD CIRCUIT

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND

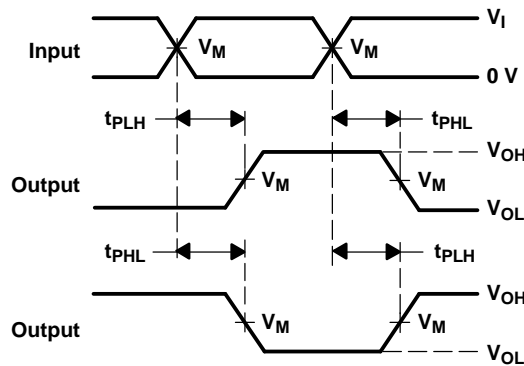
V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V
$3.3\text{ V} \pm 0.3\text{ V}$	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V



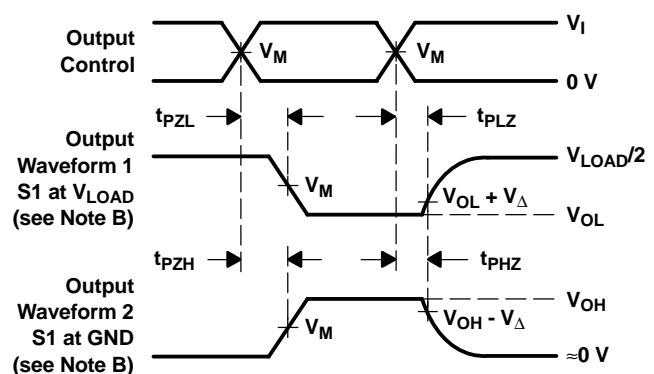
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PZL} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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- Low Supply Voltage Range 1.8 V to 3.6 V
- Ultralow-Power Consumption
 - Active Mode: 160 μ A at 1 MHz, 2.2 V
 - Standby Mode: 0.7 μ A
 - Off Mode (RAM Retention): 0.1 μ A
- Wake-Up From Standby Mode in less than 6 μ s
- 16-Bit RISC Architecture, 125 ns Instruction Cycle Time
- Basic Clock Module Configurations:
 - Various Internal Resistors
 - Single External Resistor
 - 32-kHz Crystal
 - High-Frequency Crystal
 - Resonator
 - External Clock Source
- 16-Bit Timer_A With Three Capture/Compare Registers
- On-Chip Comparator for Analog Signal Compare Function or Slope A/D Conversion
- Serial Onboard Programming, No External Programming Voltage Needed Programmable Code Protection by Security Fuse
- Family Members Include:
 - MSP430C1101: 1KB ROM, 128B RAM
 - MSP430C1111: 2KB ROM, 128B RAM
 - MSP430C1121: 4KB ROM, 256B RAM
 - MSP430F1101A: 1KB + 128B Flash Memory 128B RAM
 - MSP430F1111A: 2KB + 256B Flash Memory 128B RAM
 - MSP430F1121A: 4KB + 256B Flash Memory 256B RAM
- Available in a 20-Pin Plastic Small-Outline Wide Body (SOWB) Package, 20-Pin Plastic Small-Outline Thin Package, 20-Pin TVSOP (F11x1A only) and 24-Pin QFN
- For Complete Module Descriptions, Refer to the *MSP430x1xx Family User's Guide*, Literature Number SLAU049

description

The Texas Instruments MSP430 family of ultralow power microcontrollers consist of several devices featuring different sets of peripherals targeted for various applications. The architecture, combined with five low power modes is optimized to achieve extended battery life in portable measurement applications. The device features a powerful 16-bit RISC CPU, 16-bit registers, and constant generators that attribute to maximum code efficiency. The digitally controlled oscillator (DCO) allows wake-up from low-power modes to active mode in less than 6 μ s. The MSP430x11x1(A) series is an ultralow-power mixed signal microcontroller with a built-in 16-bit timer, versatile analog comparator and fourteen I/O pins.

Typical applications include sensor systems that capture analog signals, convert them to digital values, and then process the data for display or for transmission to a host system. Stand alone RF sensor front end is another area of application. The I/O port inputs provide single slope A/D conversion capability on resistive sensors.

AVAILABLE OPTIONS

TA	PACKAGED DEVICES			
	PLASTIC 20-PIN SOWB (DW)	PLASTIC 20-PIN TSSOP (PW)	PLASTIC 20-PIN TVSOP (DGV)	PLASTIC 24-PIN QFN (RGE)
-40°C to 85°C	MSP430C1101IDW MSP430C1111IDW MSP430C1121IDW MSP430F1101AIDW MSP430F1111AIDW MSP430F1121AIDW	MSP430C1101IPW MSP430C1111IPW MSP430C1121IPW MSP430F1101AIPW MSP430F1111AIPW MSP430F1121AIPW	MSP430F1101AIDGV MSP430F1111AIDGV MSP430F1121AIDGV	MSP430C1101IRGE MSP430C1111IRGE MSP430C1121IRGE MSP430F1101AIRGE MSP430F1111AIRGE MSP430F1121AIRGE



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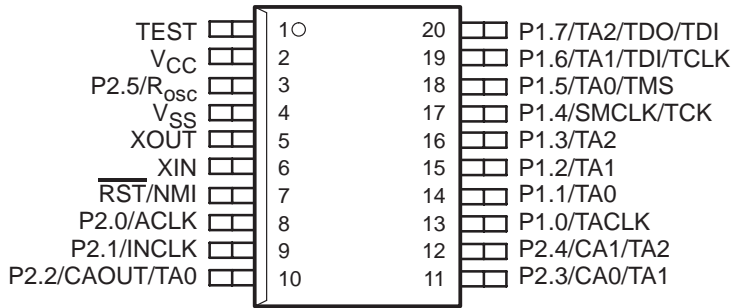
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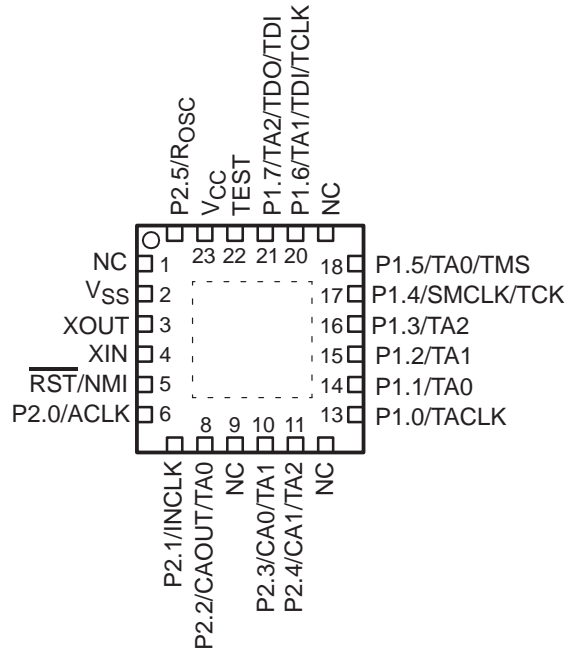
MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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DW, PW, or DGV PACKAGE
(TOP VIEW)

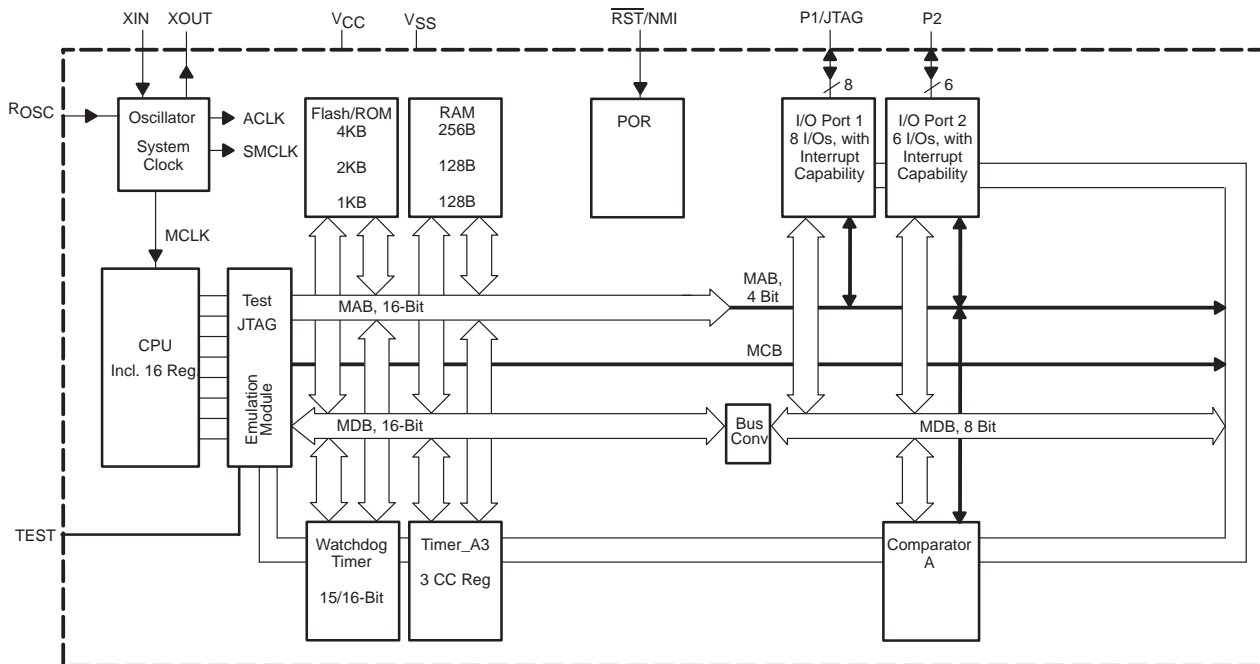


RGE PACKAGE
(TOP VIEW)



Note: NC pins not internally connected
Power Pad connection to V_{SS} recommended

functional block diagram



MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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Terminal Functions

TERMINAL				DESCRIPTION
NAME	DW, PW, or DGV NO.	RGE NO.	I/O	
P1.0/TACLK	13	13	I/O	General-purpose digital I/O pin/Timer_A, clock signal TACLK input
P1.1/TA0	14	14	I/O	General-purpose digital I/O pin/Timer_A, capture: CC10A input, compare: Out0 output/BSL transmit
P1.2/TA1	15	15	I/O	General-purpose digital I/O pin/Timer_A, capture: CC11A input, compare: Out1 output
P1.3/TA2	16	16	I/O	General-purpose digital I/O pin/Timer_A, capture: CC12A input, compare: Out2 output
P1.4/SMCLK/TCK	17	17	I/O	General-purpose digital I/O pin/SMCLK signal output/test clock, input terminal for device programming and test
P1.5/TA0/TMS	18	18	I/O	General-purpose digital I/O pin/Timer_A, compare: Out0 output/test mode select, input terminal for device programming and test
P1.6/TA1/TDI/TCLK	19	20	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output/test data input or test clock input
P1.7/TA2/TDO/TDI†	20	21	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/test data output terminal or data input during programming
P2.0/ACLK	8	6	I/O	General-purpose digital I/O pin/ACLK output
P2.1/INCLK	9	7	I/O	General-purpose digital I/O pin/Timer_A, clock signal at INCLK
P2.2/CAOUT/TA0	10	8	I/O	General-purpose digital I/O pin/Timer_A, capture: CC10B input/comparator_A, output/BSL receive
P2.3/CA0/TA1	11	10	I/O	General-purpose digital I/O pin/Timer_A, compare: Out1 output/comparator_A, input
P2.4/CA1/TA2	12	11	I/O	General-purpose digital I/O pin/Timer_A, compare: Out2 output/comparator_A, input
P2.5/ROSC	3	24	I/O	General-purpose digital I/O pin/input for external resistor that defines the DCO nominal frequency
RST/NMI	7	5	I	Reset or nonmaskable interrupt input
TEST	1	22	I	Selects test mode for JTAG pins on Port1. The device protection fuse is connected to TEST.
VCC	2	23		Supply voltage
VSS	4	2		Ground reference
XIN	6	4	I	Input terminal of crystal oscillator
XOUT	5	3	O	Output terminal of crystal oscillator
QFN Pad	NA	Package Pad	NA	QFN package pad connection to VSS recommended.

† TDO or TDI is selected via JTAG instruction.



MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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short-form description

CPU

The MSP430 CPU has a 16-bit RISC architecture that is highly transparent to the application. All operations, other than program-flow instructions, are performed as register operations in conjunction with seven addressing modes for source operand and four addressing modes for destination operand.

The CPU is integrated with 16 registers that provide reduced instruction execution time. The register-to-register operation execution time is one cycle of the CPU clock.

Four of the registers, R0 to R3, are dedicated as program counter, stack pointer, status register, and constant generator respectively. The remaining registers are general-purpose registers.

Peripherals are connected to the CPU using data, address, and control buses, and can be handled with all instructions.

instruction set

The instruction set consists of 51 instructions with three formats and seven address modes. Each instruction can operate on word and byte data. Table 1 shows examples of the three types of instruction formats; the address modes are listed in Table 2.

Program Counter	PC/R0
Stack Pointer	SP/R1
Status Register	SR/CG1/R2
Constant Generator	CG2/R3
General-Purpose Register	R4
General-Purpose Register	R5
General-Purpose Register	R6
General-Purpose Register	R7
General-Purpose Register	R8
General-Purpose Register	R9
General-Purpose Register	R10
General-Purpose Register	R11
General-Purpose Register	R12
General-Purpose Register	R13
General-Purpose Register	R14
General-Purpose Register	R15

Table 1. Instruction Word Formats

Dual operands, source-destination	e.g. ADD R4,R5	R4 + R5 ----> R5
Single operands, destination only	e.g. CALL R8	PC ---->(TOS), R8----> PC
Relative jump, un/conditional	e.g. JNE	Jump-on-equal bit = 0

Table 2. Address Mode Descriptions

ADDRESS MODE	S	D	SYNTAX	EXAMPLE	OPERATION
Register	●	●	MOV Rs,Rd	MOV R10,R11	R10 ----> R11
Indexed	●	●	MOV X(Rn),Y(Rm)	MOV 2(R5),6(R6)	M(2+R5)----> M(6+R6)
Symbolic (PC relative)	●	●	MOV EDE,TONI		M(EDE) ----> M(TONI)
Absolute	●	●	MOV &MEM,&TCDAT		M(MEM) ----> M(TCDAT)
Indirect	●		MOV @Rn,Y(Rm)	MOV @R10,Tab(R6)	M(R10) ----> M(Tab+R6)
Indirect autoincrement	●		MOV @Rn+,Rm	MOV @R10+,R11	M(R10) ----> R11 R10 + 2----> R10
Immediate	●		MOV #X,TONI	MOV #45,TONI	#45 ----> M(TONI)

NOTE: S = source D = destination



operating modes

The MSP430 has one active mode and five software selectable low-power modes of operation. An interrupt event can wake up the device from any of the five low-power modes, service the request and restore back to the low-power mode on return from the interrupt program.

The following six operating modes can be configured by software:

- Active mode AM;
 - All clocks are active
- Low-power mode 0 (LPM0);
 - CPU is disabled
ACLK and SMCLK remain active. MCLK is disabled
- Low-power mode 1 (LPM1);
 - CPU is disabled
ACLK and SMCLK remain active. MCLK is disabled
DCO's dc-generator is disabled if DCO not used in active mode
- Low-power mode 2 (LPM2);
 - CPU is disabled
MCLK and SMCLK are disabled
DCO's dc-generator remains enabled
ACLK remains active
- Low-power mode 3 (LPM3);
 - CPU is disabled
MCLK and SMCLK are disabled
DCO's dc-generator is disabled
ACLK remains active
- Low-power mode 4 (LPM4);
 - CPU is disabled
ACLK is disabled
MCLK and SMCLK are disabled
DCO's dc-generator is disabled
Crystal oscillator is stopped

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interrupt vector addresses

The interrupt vectors and the power-up starting address are located in the address range of 0FFFFh–0FFE0h. The vector contains the 16-bit address of the appropriate interrupt handler instruction sequence.

INTERRUPT SOURCE	INTERRUPT FLAG	SYSTEM INTERRUPT	WORD ADDRESS	PRIORITY
Power-up External reset Watchdog Flash Memory	WDTIFG KEYV (see Note 1)	Reset	0FFFEh	15, highest
NMI Oscillator fault Flash memory access violation	NMIIFG OFIFG ACCVIFG (see Notes 1 & 4)	(non)-maskable, (non)-maskable, (non)-maskable	0FFFCh	14
			0FFFAh	13
			0FFF8h	12
Comparator_A	CAIFG	maskable	0FFF6h	11
Watchdog Timer	WDTIFG	maskable	0FFF4h	10
Timer_A3	TACCR0 CCIFG (see Note 2)	maskable	0FFF2h	9
Timer_A3	TACCR1 CCIFG. TACCR2 CCIFG TAIFG (see Notes 1 & 2)	maskable	0FFF0h	8
			0FFEEh	7
			0FFECCh	6
			0FFEAh	5
			0FFE8h	4
I/O Port P2 (eight flags; see Note 3)	P2IFG.0 to P2IFG.7 (see Notes 1 & 2)	maskable	0FFE6h	3
I/O Port P1 (eight flags)	P1IFG.0 to P1IFG.7 (see Notes 1 & 2)	maskable	0FFE4h	2
			0FFE2h	1
			0FFE0h	0, lowest

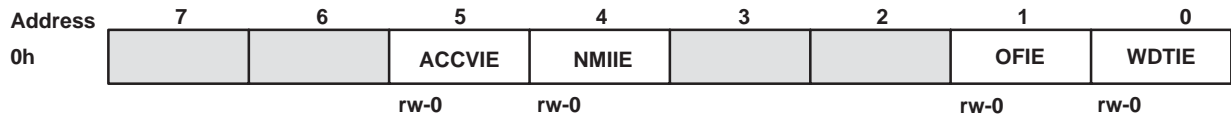
- NOTES:
- Multiple source flags
 - Interrupt flags are located in the module
 - There are eight Port P2 interrupt flags, but only six Port P2 I/O pins (P2.0–5) implemented on the 'C11x1 and 'F11x1A devices.
 - (non)-maskable: the individual interrupt-enable bit can disable an interrupt event, but the general interrupt enable cannot.
Nonmaskable: neither the individual nor the general interrupt-enable bit will disable an interrupt event.



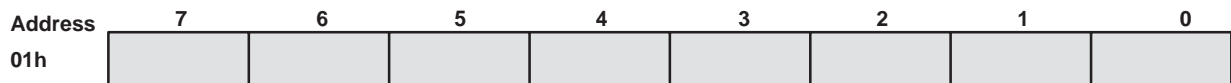
special function registers

Most interrupt and module enable bits are collected into the lowest address space. Special function register bits not allocated to a functional purpose are not physically present in the device. Simple software access is provided with this arrangement.

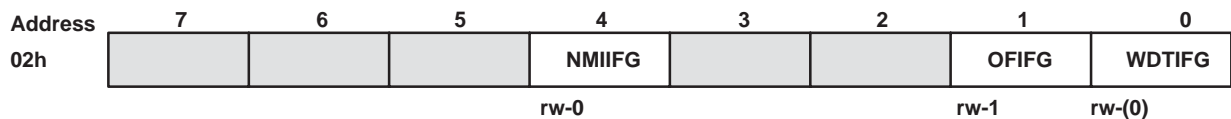
interrupt enable 1 and 2



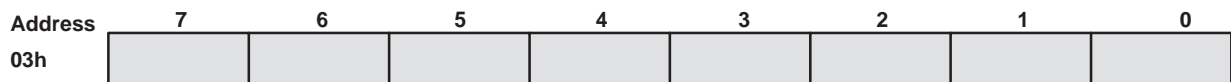
- WDTIE: Watchdog Timer interrupt enable. Inactive if watchdog mode is selected. Active if Watchdog Timer is configured in interval timer mode.
- OFIE: Oscillator fault enable
- NMIIE: (Non)maskable interrupt enable
- ACCVIE: Flash access violation interrupt enable



interrupt flag register 1 and 2



- WDTIFG: Set on Watchdog Timer overflow (in watchdog mode) or security key violation. Reset on V_{CC} power-up or a reset condition at RST/NMI pin in reset mode.
- OFIFG: Flag set on oscillator fault
- NMIIFG: Set via RST/NMI-pin



- Legend**
- rw:** Bit can be read and written.
- rw-0,1:** Bit can be read and written. It is Reset or Set by PUC.
- rw-(0,1):** Bit can be read and written. It is Reset or Set by POR.
- SFR bit is not present in device

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memory organization

		MSP430C1101	MSP430C1111	MSP430C1121
Memory Main: interrupt vector Main: code memory	Size ROM	1KB ROM 0FFFFh–0FFE0h 0FFFFh–0FC00h	2KB ROM 0FFFFh–0FFE0h 0FFFFh–0F800h	4KB ROM 0FFFFh–0FFE0h 0FFFFh–0F000h
	Information memory	Not applicable	Not applicable	Not applicable
Boot memory	Size ROM	Not applicable	Not applicable	Not applicable
RAM	Size	128 Byte 027Fh – 0200h	128 Byte 027Fh – 0200h	256 Byte 02FFh – 0200h
Peripherals	16-bit 8-bit 8-bit SFR	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h

		MSP430F1101A	MSP430F1111A	MSP430F1121A
Memory Main: interrupt vector Main: code memory	Size Flash	1KB Flash 0FFFFh–0FFE0h 0FFFFh–0FC00h	2KB Flash 0FFFFh–0FFE0h 0FFFFh–0F800h	4KB Flash 0FFFFh–0FFE0h 0FFFFh–0F000h
	Information memory	Size Flash	128 Byte 010FFh – 01080h	256 Byte 010FFh – 01000h
Boot memory	Size ROM	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h	1KB 0FFFh – 0C00h
RAM	Size	128 Byte 027Fh – 0200h	128 Byte 027Fh – 0200h	256 Byte 02FFh – 0200h
Peripherals	16-bit 8-bit 8-bit SFR	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h	01FFh – 0100h 0FFh – 010h 0Fh – 00h

bootstrap loader (BSL)

The MSP430 bootstrap loader (BSL) enables users to program the flash memory or RAM using a UART serial interface. Access to the MSP430 memory via the BSL is protected by user-defined password. For complete description of the features of the BSL and its implementation, see the Application report *Features of the MSP430 Bootstrap Loader*, Literature Number SLAA089.

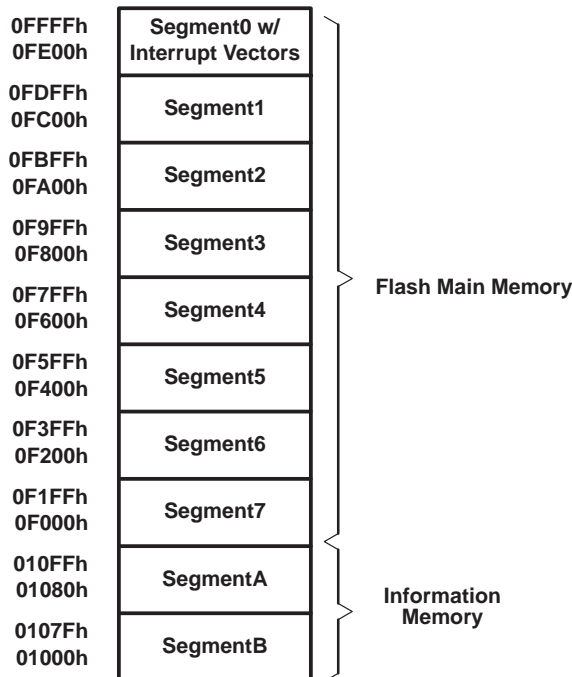
BSL Function	DW, PW & DGV Package Pins	RGE Package Pins
Data Transmit	14 - P1.1	14 - P1.1
Data Receive	10 - P2.2	8 - P2.2



flash memory

The flash memory can be programmed via the JTAG port, the bootstrap loader, or in-system by the CPU. The CPU can perform single-byte and single-word writes to the flash memory. Features of the flash memory include:

- Flash memory has n segments of main memory and two segments of information memory (A and B) of 128 bytes each. Each segment in main memory is 512 bytes in size.
- Segments 0 to n may be erased in one step, or each segment may be individually erased.
- Segments A and B can be erased individually, or as a group with segments 0–n. Segments A and B are also called *information memory*.
- New devices may have some bytes programmed in the information memory (needed for test during manufacturing). The user should perform an erase of the information memory prior to the first use.



NOTE: All segments not implemented on all devices.

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peripherals

Peripherals are connected to the CPU through data, address, and control busses and can be handled using all instructions. For complete module descriptions, refer to the *MSP430x1xx Family User's Guide*, literature number SLAU049.

oscillator and system clock

The clock system is supported by the basic clock module that includes support for a 32768-Hz watch crystal oscillator, an internal digitally-controlled oscillator (DCO) and a high frequency crystal oscillator. The basic clock module is designed to meet the requirements of both low system cost and low-power consumption. The internal DCO provides a fast turn-on clock source and stabilizes in less than 6 μ s. The basic clock module provides the following clock signals:

- Auxiliary clock (ACLK), sourced from a 32768-Hz watch crystal or a high frequency crystal.
- Main clock (MCLK), the system clock used by the CPU.
- Sub-Main clock (SMCLK), the sub-system clock used by the peripheral modules.

digital I/O

There are two 8-bit I/O ports implemented—ports P1 and P2 (only six P2 I/O signals are available on external pins):

- All individual I/O bits are independently programmable.
- Any combination of input, output, and interrupt conditions is possible.
- Edge-selectable interrupt input capability for all the eight bits of port P1 and six bits of port P2.
- Read/write access to port-control registers is supported by all instructions.

NOTE:

Six bits of port P2, P2.0 to P2.5, are available on external pins – but all control and data bits for port P2 are implemented.

watchdog timer

The primary function of the watchdog timer (WDT) module is to perform a controlled system restart after a software problem occurs. If the selected time interval expires, a system reset is generated. If the watchdog function is not needed in an application, the module can be configured as an interval timer and can generate interrupts at selected time intervals.

comparator_A

The primary function of the comparator_A module is to support precision slope analog-to-digital conversions, battery-voltage supervision, and monitoring of external analog signals.

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

Schmitt-trigger inputs – Ports P1 and P2; (P1.0 to P1.7, P2.0 to P2.5)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 2.2 V	1.1		1.5	V
		V _{CC} = 3 V	1.5		1.9	
V _{IT-}	Negative-going input threshold voltage	V _{CC} = 2.2 V	0.4		0.9	V
		V _{CC} = 3 V	0.9		1.3	
V _{hys}	Input voltage hysteresis (V _{IT+} – V _{IT-})	V _{CC} = 2.2 V	0.3		1.1	V
		V _{CC} = 3 V	0.5		1	

standard inputs – $\overline{\text{RST}}/\text{NMI}$, JTAG: TCK, TMS, TDI/TCLK

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IL}	Low-level input voltage	V _{CC} = 2.2 V / 3 V	V _{SS}		V _{SS} +0.6	V
V _{IH}	High-level input voltage		0.8×V _{CC}		V _{CC}	V

inputs P_{x.x}, TAx

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	UNIT
t _(int)	External interrupt timing	Port P1, P2: P1.x to P2.x, External trigger signal for the interrupt flag, (see Note 1)	2.2 V/3 V	1.5			cycle
			2.2 V	62			ns
			3 V	50			
t _(cap)	Timer_A, capture timing	TA0, TA1, TA2	2.2 V	62			ns
			3 V	50			
f _(TAext)	Timer_A clock frequency externally applied to pin	TACLK, INCLK t _(H) = t _(L)	2.2 V			8	MHz
			3 V			10	
f _(TAint)	Timer_A clock frequency	SMCLK or ACLK signal selected	2.2 V			8	MHz
			3 V			10	

NOTES: 1. The external signal sets the interrupt flag every time the minimum t_(int) cycle and time parameters are met. It may be set even with trigger signals shorter than t_(int). Both the cycle and timing specifications must be met to ensure the flag is set. t_(int) is measured in MCLK cycles.

leakage current

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{lkg} (P _{x.x})	High-impedance leakage current	Port P1: P1.x, 0 ≤ x ≤ 7 (see Notes 1, 2)	V _{CC} = 2.2 V/3 V,		±50	nA
		Port P2: P2.x, 0 ≤ x ≤ 5 (see Notes 1, 2)	V _{CC} = 2.2 V/3 V,		±50	

NOTES: 1. The leakage current is measured with V_{SS} or V_{CC} applied to the corresponding pin(s), unless otherwise noted.
2. The leakage of the digital port pins is measured individually. The port pin must be selected for input and there must be no optional pullup or pulldown resistor.

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

outputs – Ports P1 and P2; (P1.0 to P1.7, P2.0 to P2.5)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{OH}	High-level output voltage Port 1 and Port 2 (C11x1) Port 1 (F11x1A)	I(OHmax) = -1.5 mA	V _{CC} = 2.2 V	See Note 1	V _{CC} -0.25		V _{CC}	V
		I(OHmax) = -6 mA		See Note 2	V _{CC} -0.6		V _{CC}	
		I(OHmax) = -1.5 mA	V _{CC} = 3 V	See Note 1	V _{CC} -0.25		V _{CC}	
		I(OHmax) = -6 mA		See Note 2	V _{CC} -0.6		V _{CC}	
V _{OH}	High-level output voltage Port 2 (F11x1A)	I(OHmax) = -1 mA	V _{CC} = 2.2 V	See Note 3	V _{CC} -0.25		V _{CC}	V
		I(OHmax) = -3.4 mA		See Note 3	V _{CC} -0.6		V _{CC}	
		I(OHmax) = -1 mA	V _{CC} = 3 V	See Note 3	V _{CC} -0.25		V _{CC}	
		I(OHmax) = -3.4 mA		See Note 3	V _{CC} -0.6		V _{CC}	
V _{OL}	Low-level output voltage Port 1 and Port 2 (C11x1, F11x1A)	I(OLmax) = 1.5 mA	V _{CC} = 2.2 V	See Note 1	V _{SS}	V _{SS} +0.25	V	
		I(OLmax) = 6 mA		See Note 2	V _{SS}	V _{SS} +0.6		
		I(OLmax) = 1.5 mA	V _{CC} = 3 V	See Note 1	V _{SS}	V _{SS} +0.25		
		I(OLmax) = 6 mA		See Note 2	V _{SS}	V _{SS} +0.6		

- NOTES: 1. The maximum total current, I_{OHmax} and I_{OLmax}, for all outputs combined, should not exceed ±12 mA to hold the maximum voltage drop specified.
 2. The maximum total current, I_{OHmax} and I_{OLmax}, for all outputs combined, should not exceed ±48 mA to hold the maximum voltage drop specified.
 3. One output loaded at a time.

output frequency

PARAMETER		TEST CONDITIONS			VCC	MIN	TYP	MAX	UNIT
f _{P20}	Output frequency	P2.0/ACLK, C _L = 20 pF			2.2 V/3 V		f _{System}		MHz
f _{Tax}		TA0, TA1, TA2, C _L = 20 pF Internal clock source, SMCLK signal applied (see Note 1)			2.2 V/3 V	dc	f _{System}		
t _{Xdc}	Duty cycle of O/P frequency	P1.4/SMCLK, C _L = 20 pF	f _{SMCLK} = f _{LFXT1} = f _{XT1}		2.2 V/3 V	40%		60%	
			f _{SMCLK} = f _{LFXT1} = f _{LF}			35%		65%	
			f _{SMCLK} = f _{LFXT1} /n			50%– 15 ns	50%	50%+ 15 ns	
		f _{SMCLK} = f _{DCOCLK}		2.2 V/3 V	50%– 15 ns	50%	50%+ 15 ns		
		P2.0/ACLK, C _L = 20 pF	f _{P20} = f _{LFXT1} = f _{XT1}		2.2 V/3 V	40%		60%	
			f _{P20} = f _{LFXT1} = f _{LF}			30%		70%	
f _{P20} = f _{LFXT1} /n				50%					
t _{TAdc}	TA0, TA1, TA2, C _L = 20 pF, duty cycle = 50%			2.2 V/3 V		0	±50	ns	

NOTE 1: The limits of the system clock MCLK has to be met. MCLK and SMCLK can have different frequencies.



electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)
outputs – Ports P1 and P2 (continued)

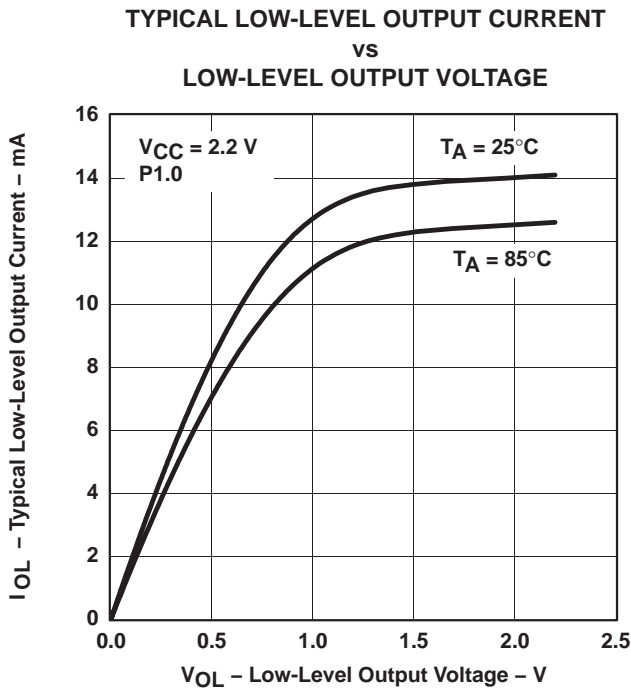


Figure 2

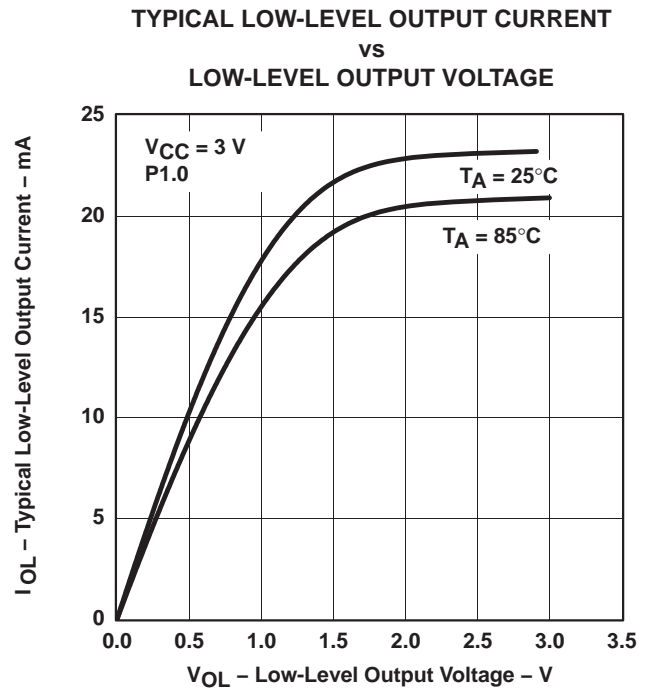


Figure 3

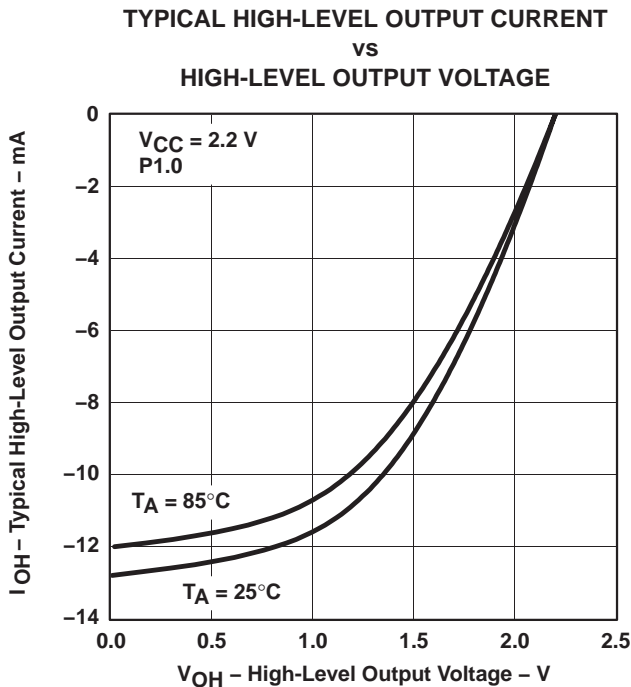


Figure 4

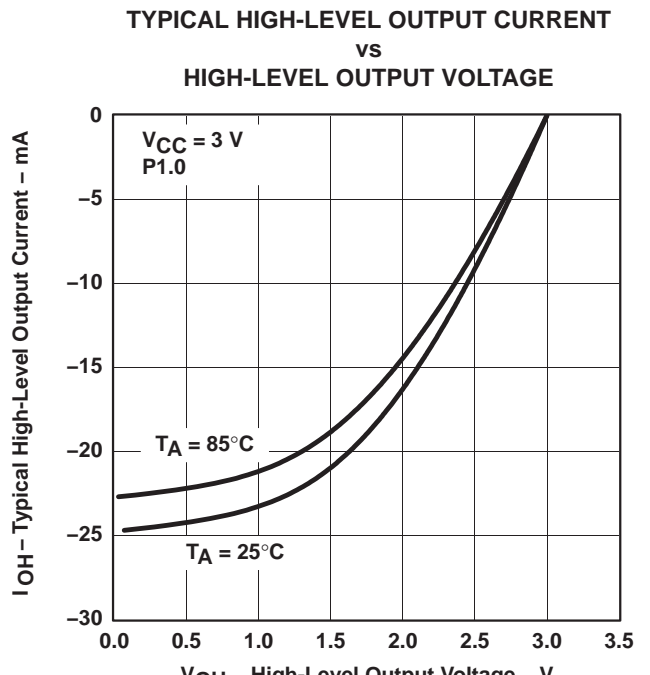


Figure 5

NOTE: One output loaded at a time.

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

optional resistors, individually programmable with ROM code (see Note 1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
R _(opt1)	Resistors, individually programmable with ROM code, all port pins, values applicable for pulldown and pullup	V _{CC} = 2.2 V/3 V	2.5	5	10	kΩ
R _(opt2)			3.8	7.7	15	kΩ
R _(opt3)			7.6	15	31	kΩ
R _(opt4)			11.5	23	46	kΩ
R _(opt5)			23	45	90	kΩ
R _(opt6)			46	90	180	kΩ
R _(opt7)			70	140	280	kΩ
R _(opt8)			115	230	460	kΩ
R _(opt9)			160	320	640	kΩ
R _(opt10)			205	420	830	kΩ

NOTE 1: Optional resistors R_{Optx} for pulldown or pullup are not available in standard flash memory device MSP430F11x1A.

wake-up from lower power modes (LPMx)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _(LPM0)	Delay time (see Note 1)	V _{CC} = 2.2 V/3 V		100		ns
t _(LPM2)		V _{CC} = 2.2 V/3 V		100		
t _(LPM3)		f _(MCLK) = 1 MHz, V _{CC} = 2.2 V/3 V			6	μs
		f _(MCLK) = 2 MHz, V _{CC} = 2.2 V/3 V			6	
		f _(MCLK) = 3 MHz, V _{CC} = 2.2 V/3 V			6	
t _(LPM4)		f _(MCLK) = 1 MHz, V _{CC} = 2.2 V/3 V			6	μs
		f _(MCLK) = 2 MHz, V _{CC} = 2.2 V/3 V			6	
		f _(MCLK) = 3 MHz, V _{CC} = 2.2 V/3 V			6	

NOTE 1: Parameter applicable only if DCOCLK is used for MCLK.

RAM

PARAMETER		MIN	NOM	MAX	UNIT
V _(RAMh)	CPU halted (see Note 1)	1.6			V

NOTE 1: This parameter defines the minimum supply voltage V_{CC} when the data in the program memory RAM remains unchanged. No program execution should happen during this supply voltage condition.



electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

Comparator_A (see Note 1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT		
I _(DD)		CAON=1, CARSEL=0, CAREF=0	V _{CC} = 2.2 V	25	40	μA		
			V _{CC} = 3 V	45	60			
I _(Refladder/RefDiode)		CAON=1, CARSEL=0, CAREF=1/2/3, no load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 2.2 V	30	50	μA		
			V _{CC} = 3 V	45	71			
V _(IC)	Common-mode input voltage	CAON =1	V _{CC} = 2.2 V/3 V		0	V _{CC} -1	V	
V _(Ref025)	$\frac{\text{Voltage @ } 0.25 V_{CC} \text{ node}}{V_{CC}}$	PCA0=1, CARSEL=1, CAREF=1, No load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 2.2 V/3 V		0.23	0.24	0.25	
V _(Ref050)	$\frac{\text{Voltage @ } 0.5 V_{CC} \text{ node}}{V_{CC}}$	PCA0=1, CARSEL=1, CAREF=2, No load at P2.3/CA0/TA1 and P2.4/CA1/TA2	V _{CC} = 2.2 V/3 V		0.47	0.48	0.5	
V _(RefVT)	(see Figure 6 and Figure 7)	PCA0=1, CARSEL=1, CAREF=3, No load at P2.3/CA0/TA1 and P2.4/CA1/TA2, T _A = 85°C	V _{CC} = 2.2 V	390	480	540	mV	
			V _{CC} = 3 V	400	490	550		
V _(offset)	Offset voltage	See Note 2	V _{CC} = 2.2 V/3 V		-30	30	mV	
V _{hys}	Input hysteresis	CAON=1	V _{CC} = 2.2 V/3 V		0	0.7	1.4	mV
t _(response LH)		T _A = 25°C, Overdrive 10 mV, Without filter: CAF=0	V _{CC} = 2.2 V	160	210	300	ns	
			V _{CC} = 3 V	90	150	240		
		T _A = 25°C, Overdrive 10 mV, With filter: CAF=1	V _{CC} = 2.2 V	1.4	1.9	3.4	μs	
			V _{CC} = 3 V	0.9	1.5	2.6		
t _(response HL)		T _A = 25°C, Overdrive 10 mV, Without filter: CAF=0	V _{CC} = 2.2 V	130	210	300	ns	
			V _{CC} = 3 V	80	150	240		
		T _A = 25°C, Overdrive 10 mV, With filter: CAF=1	V _{CC} = 2.2 V	1.4	1.9	3.4	μs	
			V _{CC} = 3 V	0.9	1.5	2.6		

- NOTES: 1. The leakage current for the Comparator_A terminals is identical to I_{kg(Px.x)} specification.
 2. The input offset voltage can be cancelled by using the CAEX bit to invert the Comparator_A inputs on successive measurements. The two successive measurements are then summed together.

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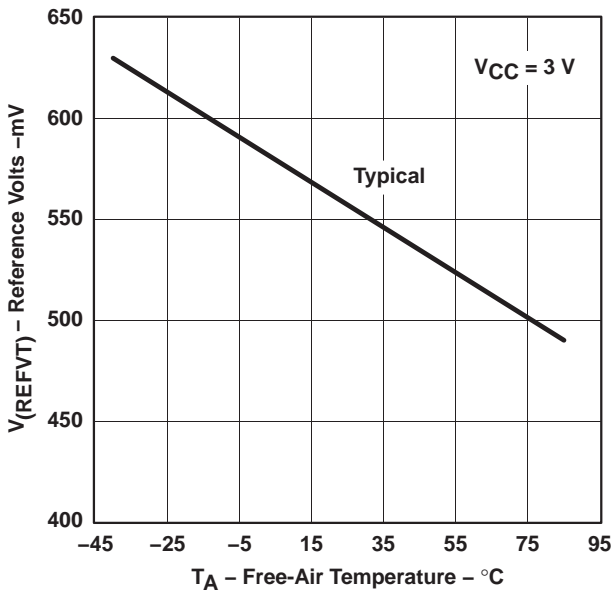


Figure 6. V(REFVT) vs Temperature, V_{CC} = 3 V

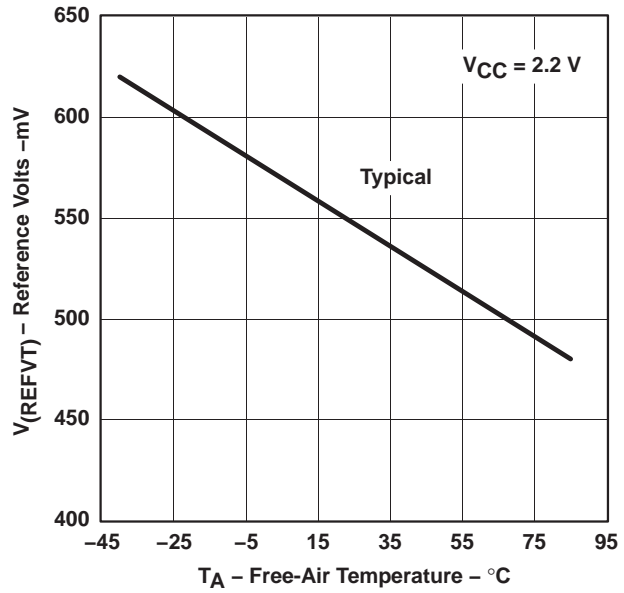


Figure 7. V(REFVT) vs Temperature, V_{CC} = 2.2 V

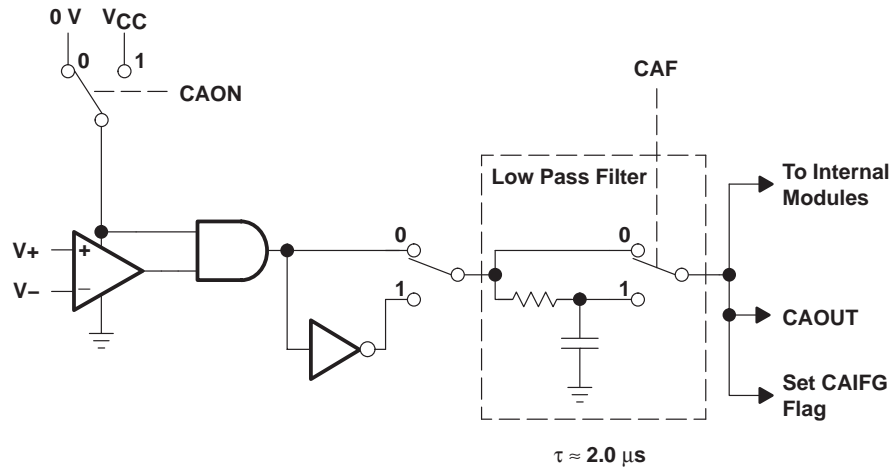


Figure 8. Block Diagram of Comparator_A Module

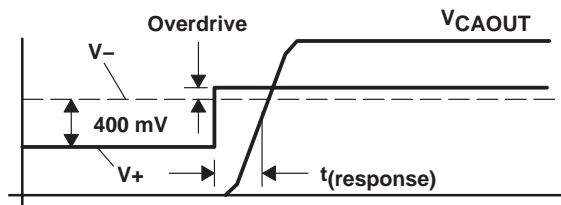


Figure 9. Overdrive Definition

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

PUC/POR

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
$t_{(POR_Delay)}$	Internal time delay to release POR		150	250	μs	
V_{POR}	V_{CC} threshold at which POR release delay time begins (see Note 1)	$T_A = -40^\circ C$		1.4	1.8	V
		$T_A = 25^\circ C$		1.1	1.5	V
		$T_A = 85^\circ C$		0.8	1.2	V
$V_{(min)}$	V_{CC} threshold required to generate a POR (see Note 2)	$V_{CC} dV/dt \geq 1V/ms$			V	
$t_{(reset)}$	\overline{RST}/NMI low time for PUC/POR	Reset is accepted internally		2	μs	

- NOTES: 1. V_{CC} rise time $dV/dt \geq 1V/ms$.
 2. When driving V_{CC} low in order to generate a POR condition, V_{CC} should be driven to 200mV or lower with a dV/dt equal to or less than $-1V/ms$. The corresponding rising V_{CC} must also meet the dV/dt requirement equal to or greater than $+1V/ms$.

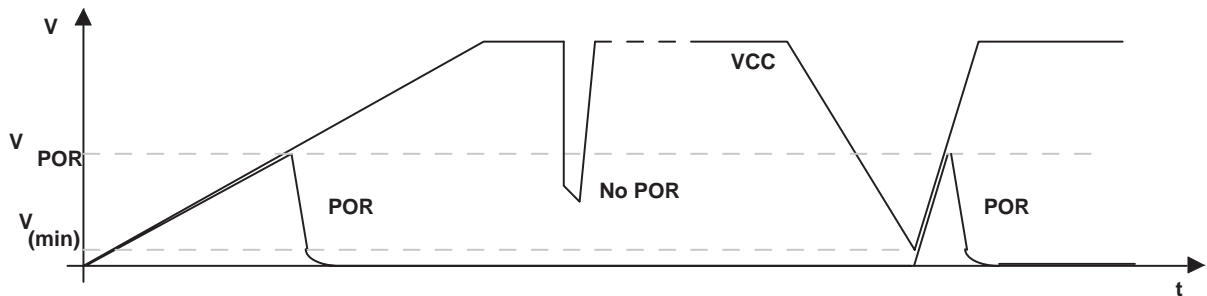


Figure 10. Power-On Reset (POR) vs Supply Voltage

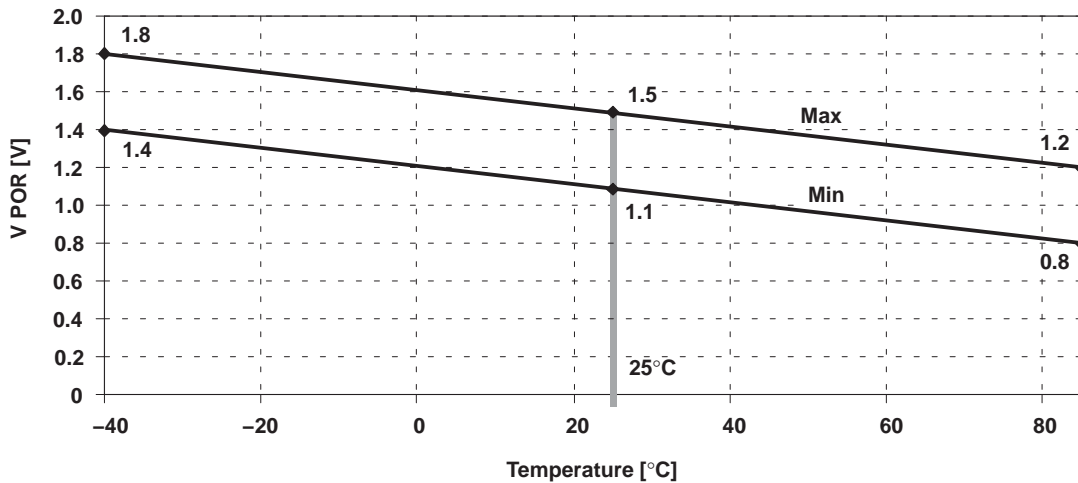


Figure 11. V_{POR} vs Temperature

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

DCO

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
f(DCO03)	R _{sel} = 0, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.08	0.12	0.15	MHz
		V _{CC} = 3 V	0.08	0.13	0.16	
f(DCO13)	R _{sel} = 1, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.14	0.19	0.23	MHz
		V _{CC} = 3 V	0.14	0.18	0.22	
f(DCO23)	R _{sel} = 2, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.22	0.30	0.36	MHz
		V _{CC} = 3 V	0.22	0.28	0.34	
f(DCO33)	R _{sel} = 3, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.37	0.49	0.59	MHz
		V _{CC} = 3 V	0.37	0.47	0.56	
f(DCO43)	R _{sel} = 4, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	0.61	0.77	0.93	MHz
		V _{CC} = 3 V	0.61	0.75	0.9	
f(DCO53)	R _{sel} = 5, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	1	1.2	1.5	MHz
		V _{CC} = 3 V	1	1.3	1.5	
f(DCO63)	R _{sel} = 6, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	1.6	1.9	2.2	MHz
		V _{CC} = 3 V	1.69	2	2.29	
f(DCO73)	R _{sel} = 7, DCO = 3, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	2.4	2.9	3.4	MHz
		V _{CC} = 3 V	2.7	3.2	3.65	
f(DCO77)	R _{sel} = 7, DCO = 7, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V	4	4.5	4.9	MHz
		V _{CC} = 3 V	4.4	4.9	5.4	
f(DCO47)	R _{sel} = 4, DCO = 7, MOD = 0, DCOR = 0, T _A = 25°C	V _{CC} = 2.2 V/3 V	f _{DCO40} x1.7	f _{DCO40} x2.1	f _{DCO40} x2.5	MHz
S(Rsel)	S _R = f _{Rsel+1} /f _{Rsel}	V _{CC} = 2.2 V/3 V	1.35	1.65	2	ratio
S(DCO)	S _{DCO} = f _{DCO+1} /f _{DCO}	V _{CC} = 2.2 V/3 V	1.07	1.12	1.16	
D _t	Temperature drift, R _{sel} = 4, DCO = 3, MOD = 0 (see Note 1)	V _{CC} = 2.2 V	-0.31	-0.36	-0.40	%/°C
		V _{CC} = 3 V	-0.33	-0.38	-0.43	
D _V	Drift with V _{CC} variation, R _{sel} = 4, DCO = 3, MOD = 0 (see Note 1)	V _{CC} = 2.2 V/3 V	0	5	10	%/V

NOTE 1: These parameters are not production tested.

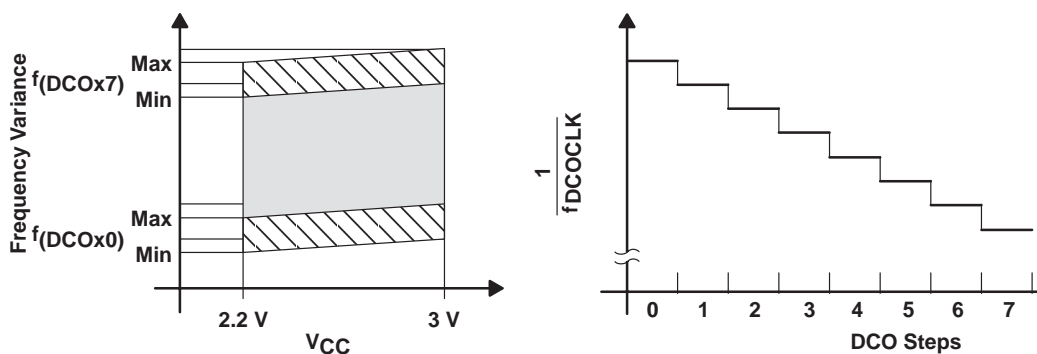


Figure 12. DCO Characteristics

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

main DCO characteristics

- Individual devices have a minimum and maximum operation frequency. The specified parameters for $f_{(DCOx0)}$ to $f_{(DCOx7)}$ are valid for all devices.
- All ranges selected by $R_{sel}(n)$ overlap with $R_{sel}(n+1)$: R_{sel0} overlaps R_{sel1} , ... R_{sel6} overlaps R_{sel7} .
- DCO control bits DCO0, DCO1, and DCO2 have a step size as defined by parameter S_{DCO} .
- Modulation control bits MOD0 to MOD4 select how often $f_{(DCO+1)}$ is used within the period of 32 DCOCLK cycles. The frequency $f_{(DCO)}$ is used for the remaining cycles. The frequency is an average equal to:

$$f_{average} = \frac{32 \times f_{(DCO)} \times f_{(DCO+1)}}{MOD \times f_{(DCO)} + (32 - MOD) \times f_{(DCO+1)}}$$

DCO when using R_{OSC} (see Note 1)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	NOM	MAX	UNIT
f _{DCO} , DCO output frequency	R _{sel} = 4, DCO = 3, MOD = 0, DCOR = 1, T _A = 25°C	2.2 V		1.8±15%		MHz
		3 V		1.95±15%		MHz
D _t , Temperature drift	R _{sel} = 4, DCO = 3, MOD = 0, DCOR = 1	2.2 V/3 V		±0.1		%/°C
D _v , Drift with V _{CC} variation	R _{sel} = 4, DCO = 3, MOD = 0, DCOR = 1	2.2 V/3 V		10		%/V

NOTES: 1. R_{OSC} = 100kΩ. Metal film resistor, type 0257. 0.6 watt with 1% tolerance and T_K = ±50ppm/°C.

crystal oscillator, LFXT1

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
C _{XIN} Input capacitance	XTS=0; LF mode selected. V _{CC} = 2.2 V / 3 V		12		pF
	XTS=1; XT1 mode selected. V _{CC} = 2.2 V / 3 V (see Note 1)		2		
C _{XOUT} Output capacitance	XTS=0; LF mode selected. V _{CC} = 2.2 V / 3 V		12		pF
	XTS=1; XT1 mode selected. V _{CC} = 2.2 V / 3 V (see Note 1)		2		
V _{IL}	Input levels at XIN V _{CC} = 2.2 V/3 V (see Note 2)	V _{SS}		0.2×V _{CC}	V
V _{IH}		0.8×V _{CC}		V _{CC}	

- NOTES: 1. Requires external capacitors at both terminals. Values are specified by crystal manufacturers.
2. Applies only when using an external logic-level clock source. Not applicable when using a crystal or resonator.

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (continued)

Flash Memory

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	NOM	MAX	UNIT
V _{CC} (PGM/ERASE)	Program and Erase supply voltage			2.7		3.6	V
f _{FTG}	Flash Timing Generator frequency			257		476	kHz
I _{PGM}	Supply current from V _{CC} during program		2.7 V/ 3.6 V		3	5	mA
I _{ERASE}	Supply current from V _{CC} during erase		2.7 V/ 3.6 V		3	7	mA
t _{CPT}	Cumulative program time	see Note 1	2.7 V/ 3.6 V			4	ms
t _{CMErase}	Cumulative mass erase time	see Note 2	2.7 V/ 3.6 V	200			ms
	Program/Erase endurance			10 ⁴	10 ⁵		cycles
t _{Retention}	Data retention duration	T _J = 25°C		100			years
t _{Word}	Word or byte program time	see Note 3			35		t _{FTG}
t _{Block, 0}	Block program time for 1 st byte or word				30		
t _{Block, 1-63}	Block program time for each additional byte or word				21		
t _{Block, End}	Block program end-sequence wait time				6		
t _{Mass Erase}	Mass erase time				5297		
t _{Seg Erase}	Segment erase time				4819		

- NOTES: 1. The cumulative program time must not be exceeded when writing to a 64-byte flash block. This parameter applies to all programming methods: individual word/byte write and block write modes.
2. The mass erase duration generated by the flash timing generator is at least 11.1ms (= 5297x1/f_{FTG,max} = 5297x1/476kHz). To achieve the required cumulative mass erase time the Flash Controller's mass erase operation can be repeated until this time is met. (A worst case minimum of 19 cycles are required).
3. These values are hardwired into the Flash Controller's state machine (t_{FTG} = 1/f_{FTG}).

JTAG Interface

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	NOM	MAX	UNIT
f _{TCK}	TCK input frequency	see Note 1	2.2 V	0		5	MHz
			3 V	0		10	MHz
R _{Internal}	Internal pull-down resistance on TEST	see Note 2	2.2 V/ 3 V	25	60	90	kΩ

- NOTES: 1. f_{TCK} may be restricted to meet the timing requirements of the module selected.
2. TEST pull-down resistor implemented in all versions.

JTAG Fuse (see Note 1)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	NOM	MAX	UNIT
V _{CC} (FB)	Supply voltage during fuse-blow condition	T _A = 25°C		2.5			V
V _{FB}	Voltage level on TEST for fuse-blow - 'C11x1			3.5		3.9	V
	Voltage level on TEST for fuse-blow - 'F11x1A			6		7	V
I _{FB}	Supply current into TEST during fuse blow					100	mA
t _{FB}	Time to blow fuse					1	ms

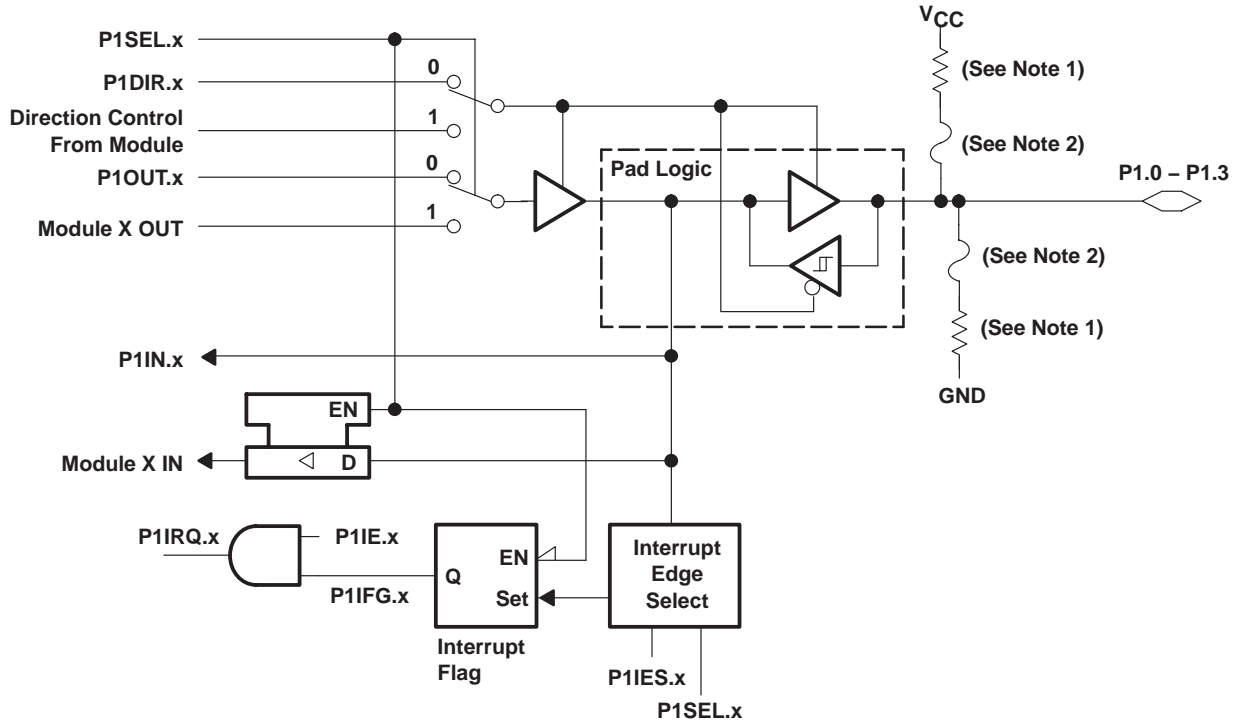
- NOTES: 1. Once the fuse is blown, no further access to the MSP430 JTAG/Test and emulation features is possible. The JTAG block is switched to bypass mode.



APPLICATION INFORMATION

input/output schematic

Port P1, P1.0 to P1.3, input/output with Schmitt-trigger



NOTE: x = Bit/identifier, 0 to 3 for port P1

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P1Sel.0	P1DIR.0	P1DIR.0	P1OUT.0	VSS	P1IN.0	TACLK [†]	P1IE.0	P1IFG.0	P1IES.0
P1Sel.1	P1DIR.1	P1DIR.1	P1OUT.1	Out0 signal [†]	P1IN.1	CCI0A [†]	P1IE.1	P1IFG.1	P1IES.1
P1Sel.2	P1DIR.2	P1DIR.2	P1OUT.2	Out1 signal [†]	P1IN.2	CCI1A [†]	P1IE.2	P1IFG.2	P1IES.2
P1Sel.3	P1DIR.3	P1DIR.3	P1OUT.3	Out2 signal [†]	P1IN.3	CCI2A [†]	P1IE.3	P1IFG.3	P1IES.3

[†] Signal from or to Timer_A

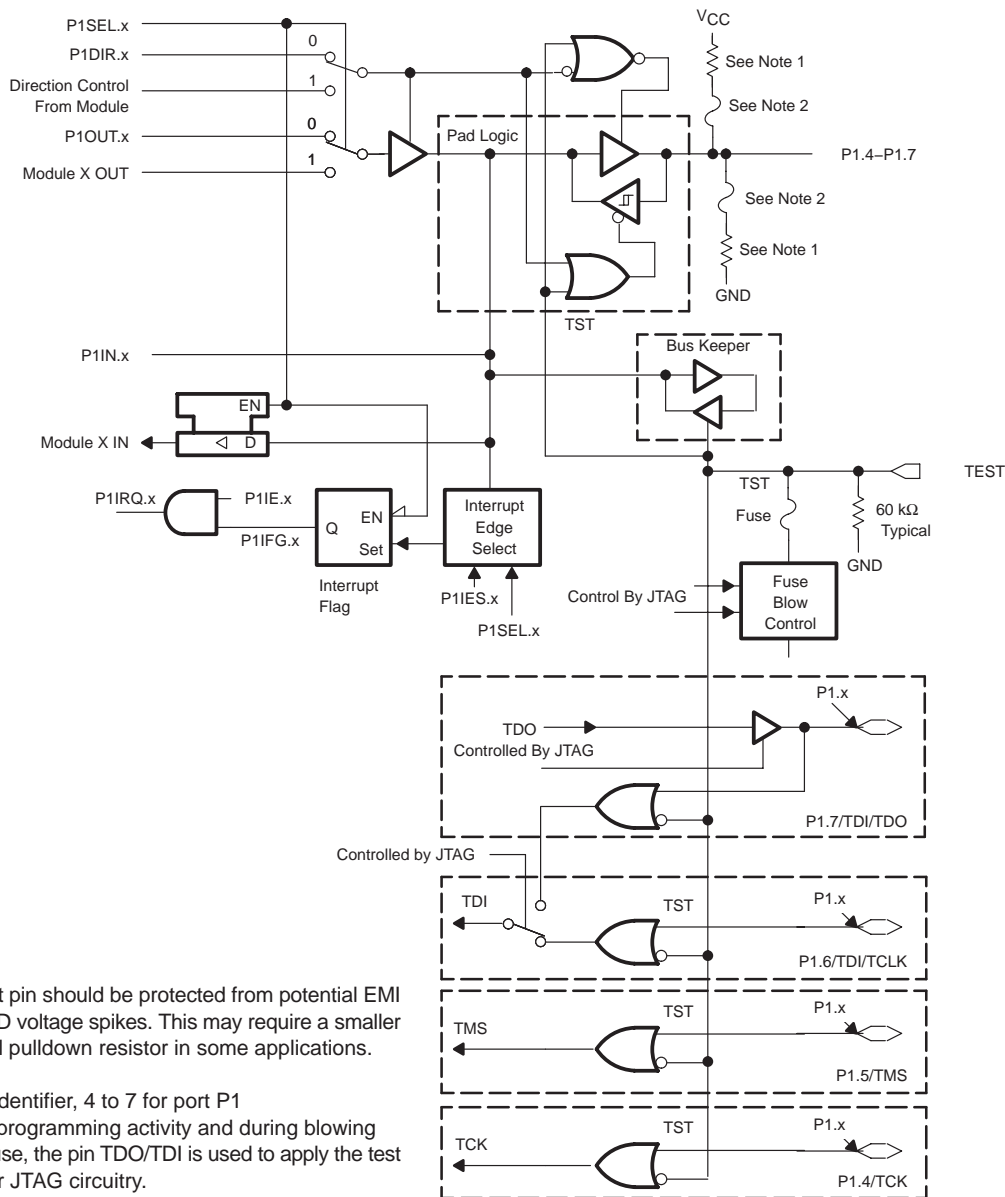
- NOTES: 1. Optional selection of pullup or pulldown resistors with ROM (masked) versions
2. Fuses for optional pullup and pulldown resistors can only be programmed at the factory (ROM versions only).

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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APPLICATION INFORMATION

Port P1, P1.4 to P1.7, input/output with Schmitt-trigger and in-system access features



NOTE: The test pin should be protected from potential EMI and ESD voltage spikes. This may require a smaller external pulldown resistor in some applications.

x = Bit identifier, 4 to 7 for port P1
During programming activity and during blowing of the fuse, the pin TDO/TDI is used to apply the test input for JTAG circuitry.

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P1Sel.4	P1DIR.4	P1DIR.4	P1OUT.4	SMCLK	P1IN.4	unused	P1IE.4	P1IFG.4	P1IES.4
P1Sel.5	P1DIR.5	P1DIR.5	P1OUT.5	Out0 signal†	P1IN.5	unused	P1IE.5	P1IFG.5	P1IES.5
P1Sel.6	P1DIR.6	P1DIR.6	P1OUT.6	Out1 signal†	P1IN.6	unused	P1IE.6	P1IFG.6	P1IES.6
P1Sel.7	P1DIR.7	P1DIR.7	P1OUT.7	Out2 signal†	P1IN.7	unused	P1IE.7	P1IFG.7	P1IES.7

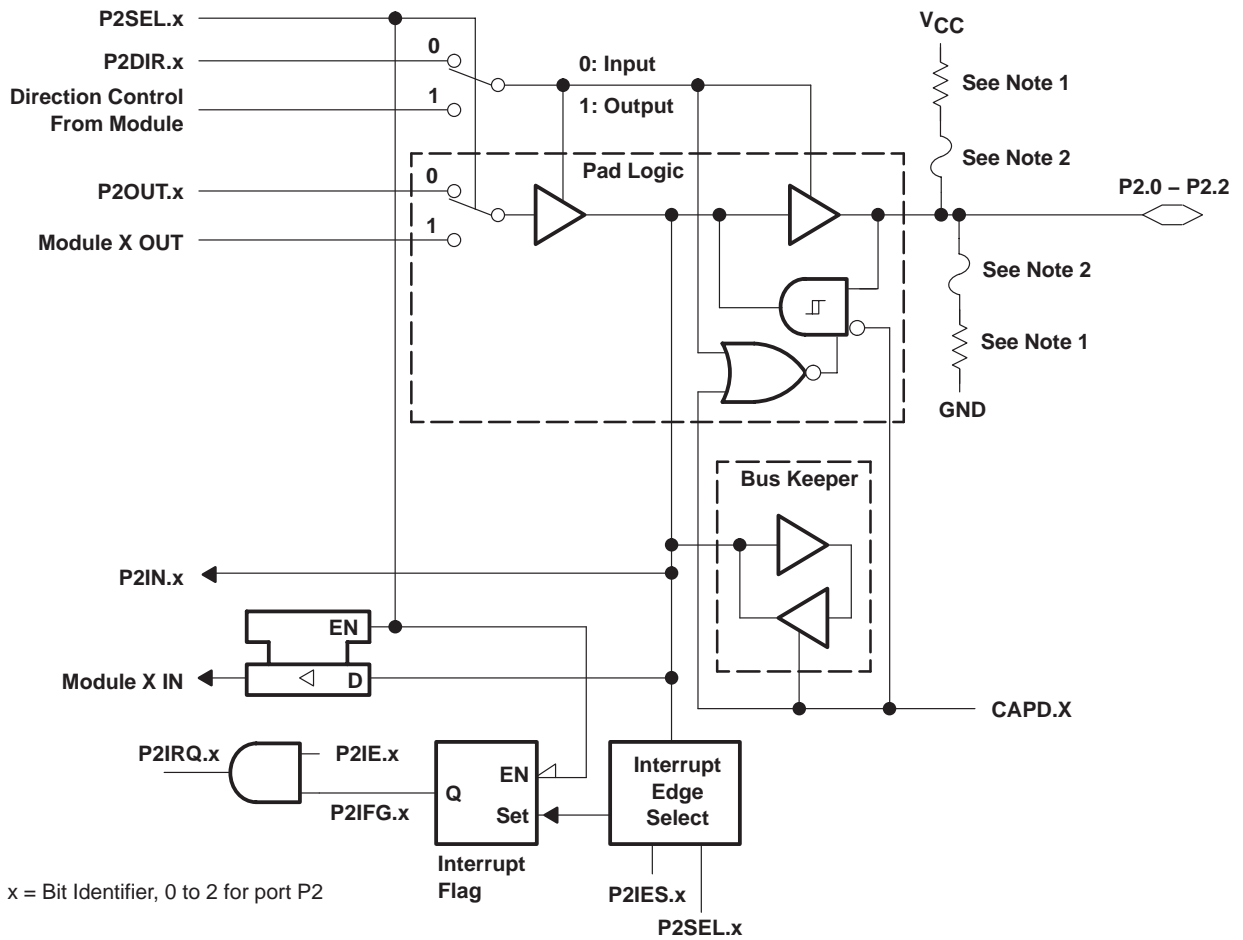
† Signal from or to Timer_A

- NOTES: 1. Optional selection of pullup or pulldown resistors with ROM (masked) versions
2. Fuses for optional pullup and pulldown resistors can only be programmed at the factory (ROM versions only).



APPLICATION INFORMATION

Port P2, P2.0 to P2.2, input/output with Schmitt-trigger



NOTE: x = Bit Identifier, 0 to 2 for port P2

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.0	P2DIR.0	P2DIR.0	P2OUT.0	ACLK	P2IN.0	unused	P2IE.0	P2IFG.0	P1IES.0
P2Sel.1	P2DIR.1	P2DIR.1	P2OUT.1	V _{SS}	P2IN.1	INCLK [†]	P2IE.1	P2IFG.1	P1IES.1
P2Sel.2	P2DIR.2	P2DIR.2	P2OUT.2	CAOUT	P2IN.2	CCI0B [†]	P2IE.2	P2IFG.2	P1IES.2

[†] Signal from or to Timer_A

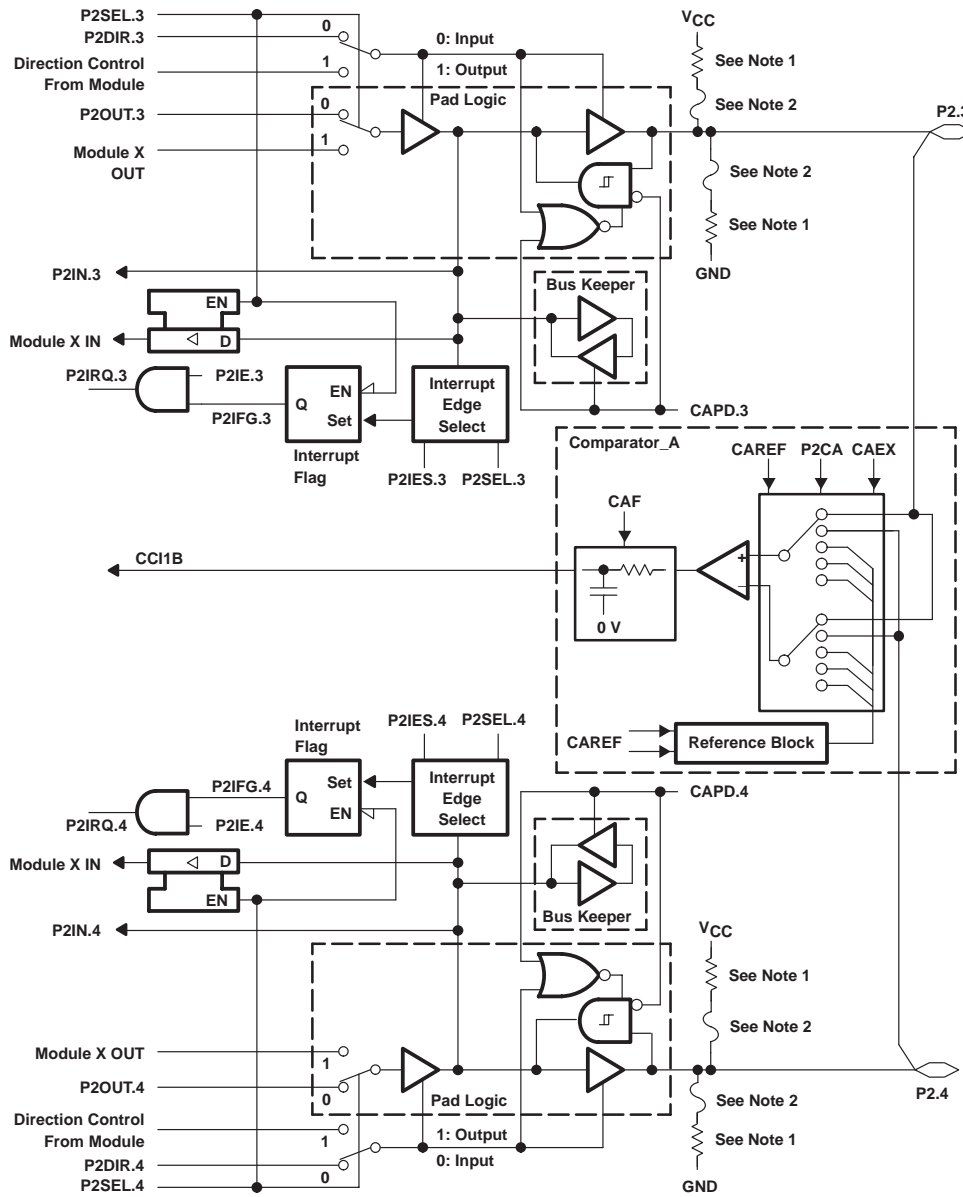
- NOTES: 1. Optional selection of pullup or pulldown resistors with ROM (masked) versions
2. Fuses for optional pullup and pulldown resistors can only be programmed at the factory (ROM versions only).

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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APPLICATION INFORMATION

Port P2, P2.3 to P2.4, input/output with Schmitt-trigger



PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.3	P2DIR.3	P2DIR.3	P2OUT.3	Out1 signal [†]	P2IN.3	unused	P2IE.3	P2IFG.3	P1IES.3
P2Sel.4	P2DIR.4	P2DIR.4	P2OUT.4	Out2 signal [†]	P2IN.4	unused	P2IE.4	P2IFG.4	P1IES.4

[†] Signal from Timer_A

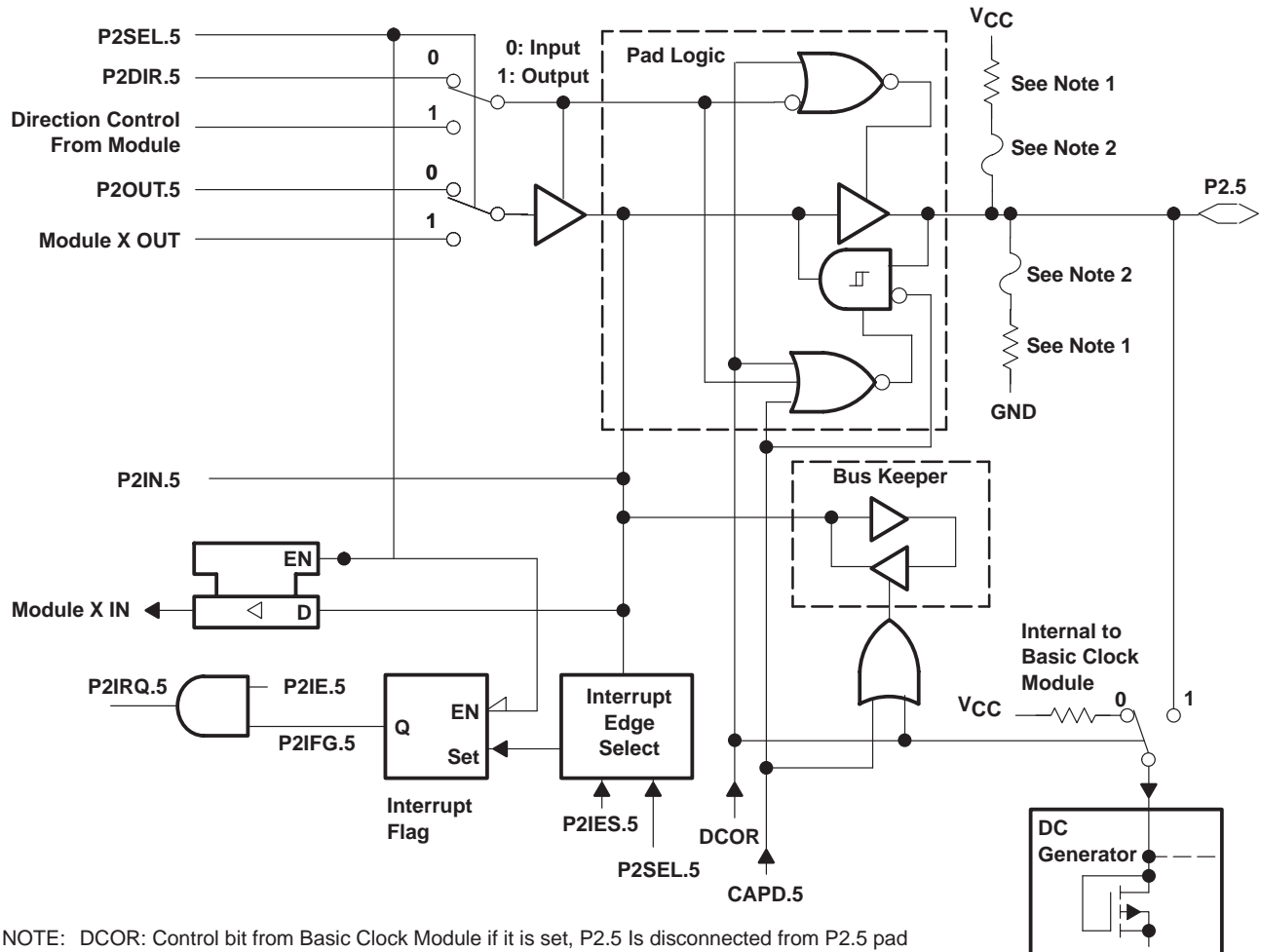
NOTES: 1. Optional selection of pullup or pulldown resistors with ROM (masked) versions
2. Fuses for optional pullup and pulldown resistors can only be programmed at the factory (ROM versions only).



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APPLICATION INFORMATION

Port P2, P2.5, input/output with Schmitt-trigger and R_{OSC} function for the Basic Clock module



NOTE: DCOR: Control bit from Basic Clock Module if it is set, P2.5 is disconnected from P2.5 pad

PnSel.x	PnDIR.x	Direction control from module	PnOUT.x	Module X OUT	PnIN.x	Module X IN	PnIE.x	PnIFG.x	PnIES.x
P2Sel.5	P2DIR.5	P2DIR.5	P2OUT.5	V _{SS}	P2IN.5	unused	P2IE.5	P2IFG.5	P2IES.5

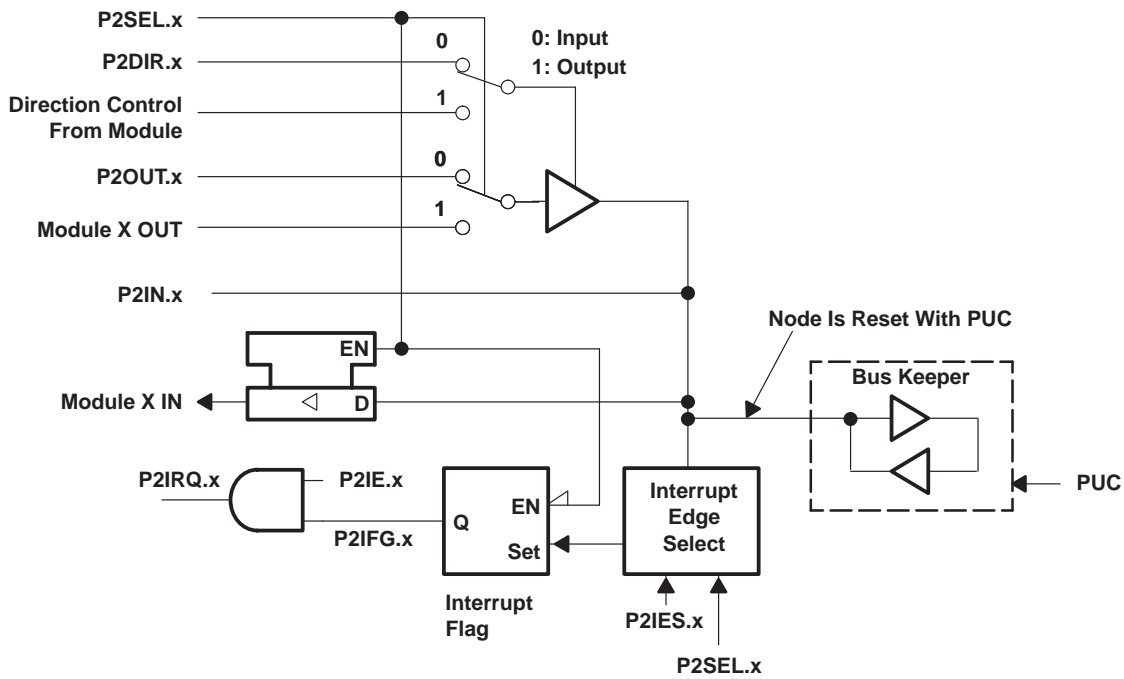
- NOTES: 1. Optional selection of pullup or pulldown resistors with ROM (masked) versions
2. Fuses for optional pullup and pulldown resistors can only be programmed at the factory (ROM versions only).

MSP430C11x1, MSP430F11x1A MIXED SIGNAL MICROCONTROLLER

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APPLICATION INFORMATION

Port P2, unbonded bits P2.6 and P2.7



NOTE: x = Bit/identifier, 6 to 7 for port P2 without external pins

P2Sel.x	P2DIR.x	Direction control from module	P2OUT.x	Module X OUT	P2IN.x	Module X IN	P2IE.x	P2IFG.x	P2IES.x
P2Sel.6	P2DIR.6	P2DIR.6	P2OUT.6	V _{SS}	P2IN.6	unused	P2IE.6	P2IFG.6	P2IES.6
P2Sel.7	P2DIR.7	P2DIR.7	P2OUT.7	V _{SS}	P2IN.7	unused	P2IE.7	P2IFG.7	P2IES.7

NOTE 1: Unbonded bits 6 and 7 of port P2 can be used as software interrupt flags. The interrupt flags can only be influenced by software. They work then as a software interrupt.

JTAG fuse check mode

MSP430 devices that have the fuse on the TEST terminal have a fuse check mode that tests the continuity of the fuse the first time the JTAG port is accessed after a power-on reset (POR). When activated, a fuse check current, I_{TF} , of 1 mA at 3 V, 2.5 mA at 5 V can flow from the TEST pin to ground if the fuse is not burned. Care must be taken to avoid accidentally activating the fuse check mode and increasing overall system power consumption.

When the TEST pin is taken back low after a test or programming session, the fuse check mode and sense currents are terminated.

Activation of the fuse check mode occurs with the first negative edge on the TMS pin after power up or if TMS is being held low during power up. The second positive edge on the TMS pin deactivates the fuse check mode. After deactivation, the fuse check mode remains inactive until another POR occurs. After each POR the fuse check mode has the potential to be activated.

The fuse check current will only flow when the fuse check mode is active and the TMS pin is in a low state (see Figure 13). Therefore, the additional current flow can be prevented by holding the TMS pin high (default condition).

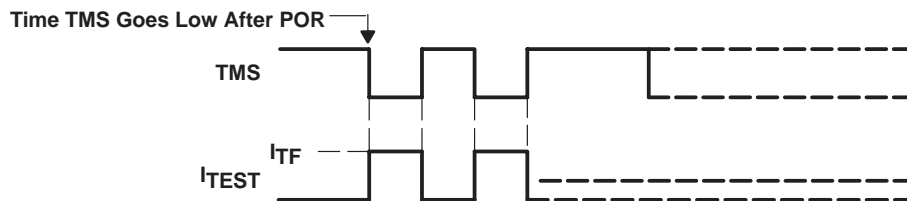


Figure 13. Fuse Check Mode Current, MSP430F11x1A and MSP430C11x1

NOTE:

The CODE and RAM data protection is ensured if the JTAG fuse is blown and the 256-bit bootloader access key is used. Also, see the *bootstrap loader* section for more information.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MSP430C1101	ACTIVE					TBD	Call TI	Call TI
MSP430F1101AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

DW (R-PDSO-G20)

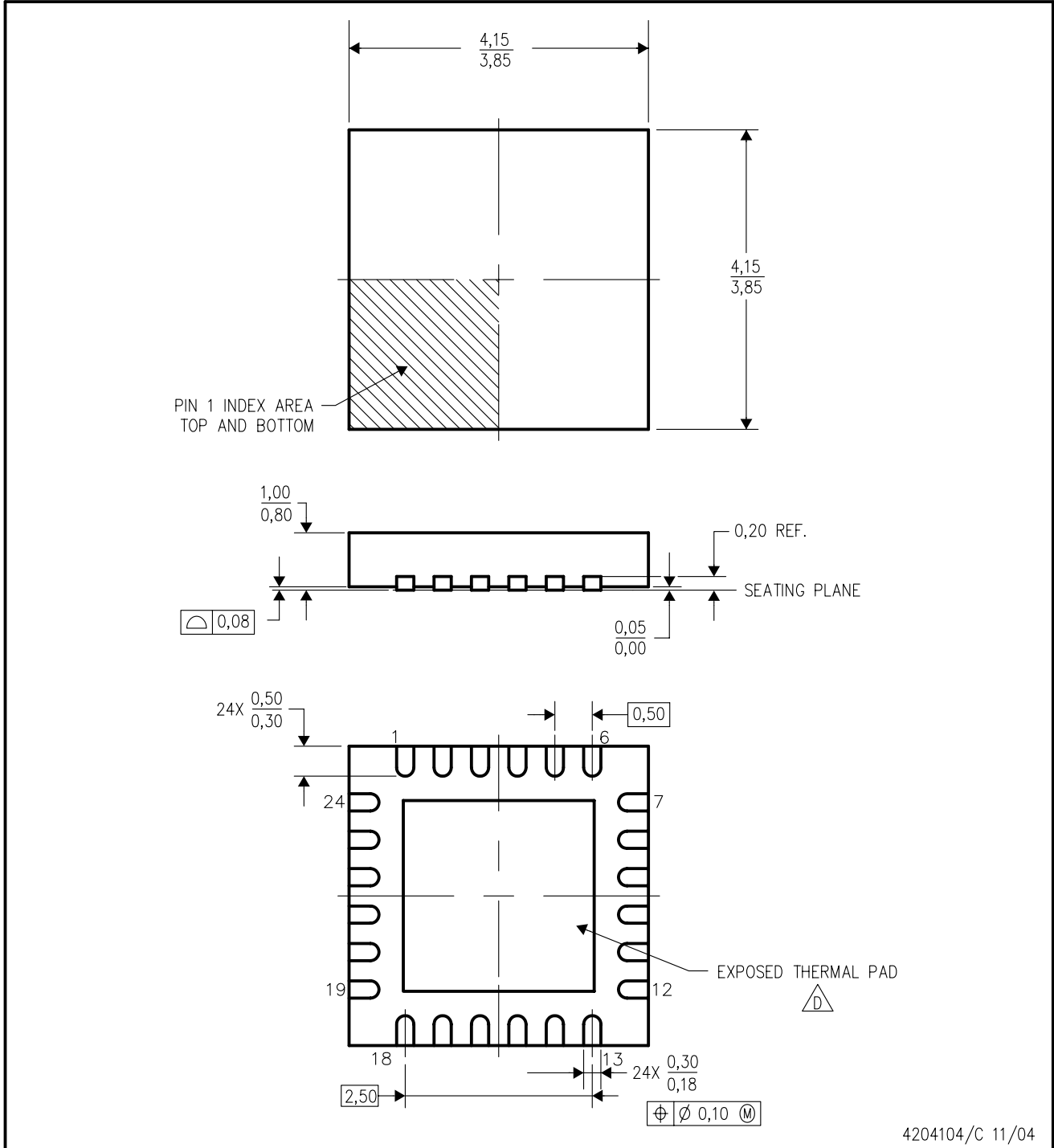
PLASTIC SMALL-OUTLINE PACKAGE




- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AC.

RGE (S-PQFP-N24)

PLASTIC QUAD FLATPACK



4204104/C 11/04

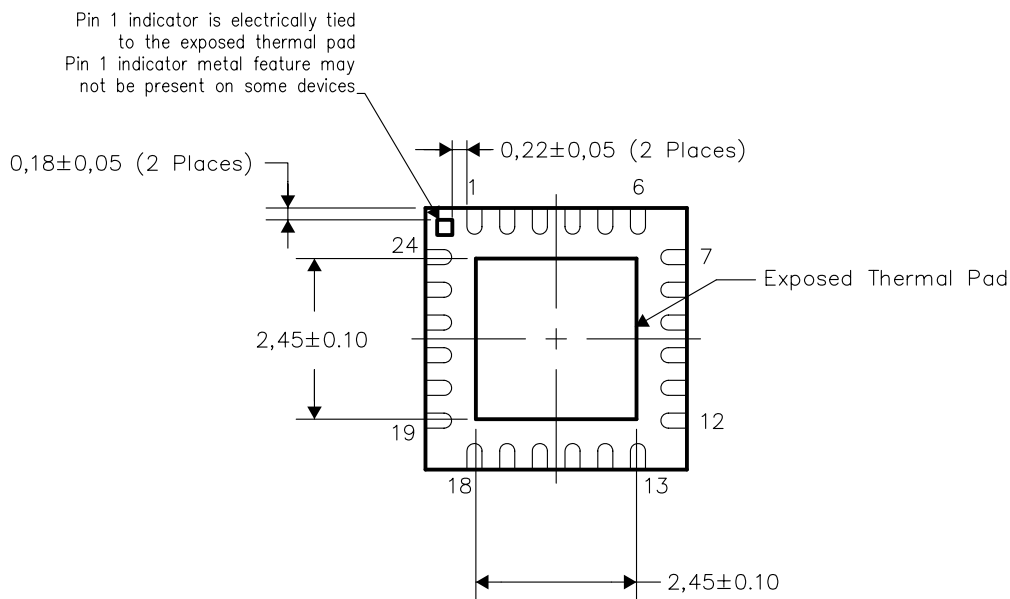
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Quad Flatpack, No-Leads (QFN) package configuration.
 -  The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
 - E. Falls within JEDEC MO-220.

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to a ground or power plane (whichever is applicable), or alternatively, a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MSP430C1101	ACTIVE					TBD	Call TI	Call TI
MSP430F1101AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1101AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1101AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1111AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1111AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDGV	ACTIVE	TVSOP	DGV	20	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MSP430F1121AIRGER	ACTIVE	QFN	RGE	24	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
MSP430F1121AIRGET	ACTIVE	QFN	RGE	24	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

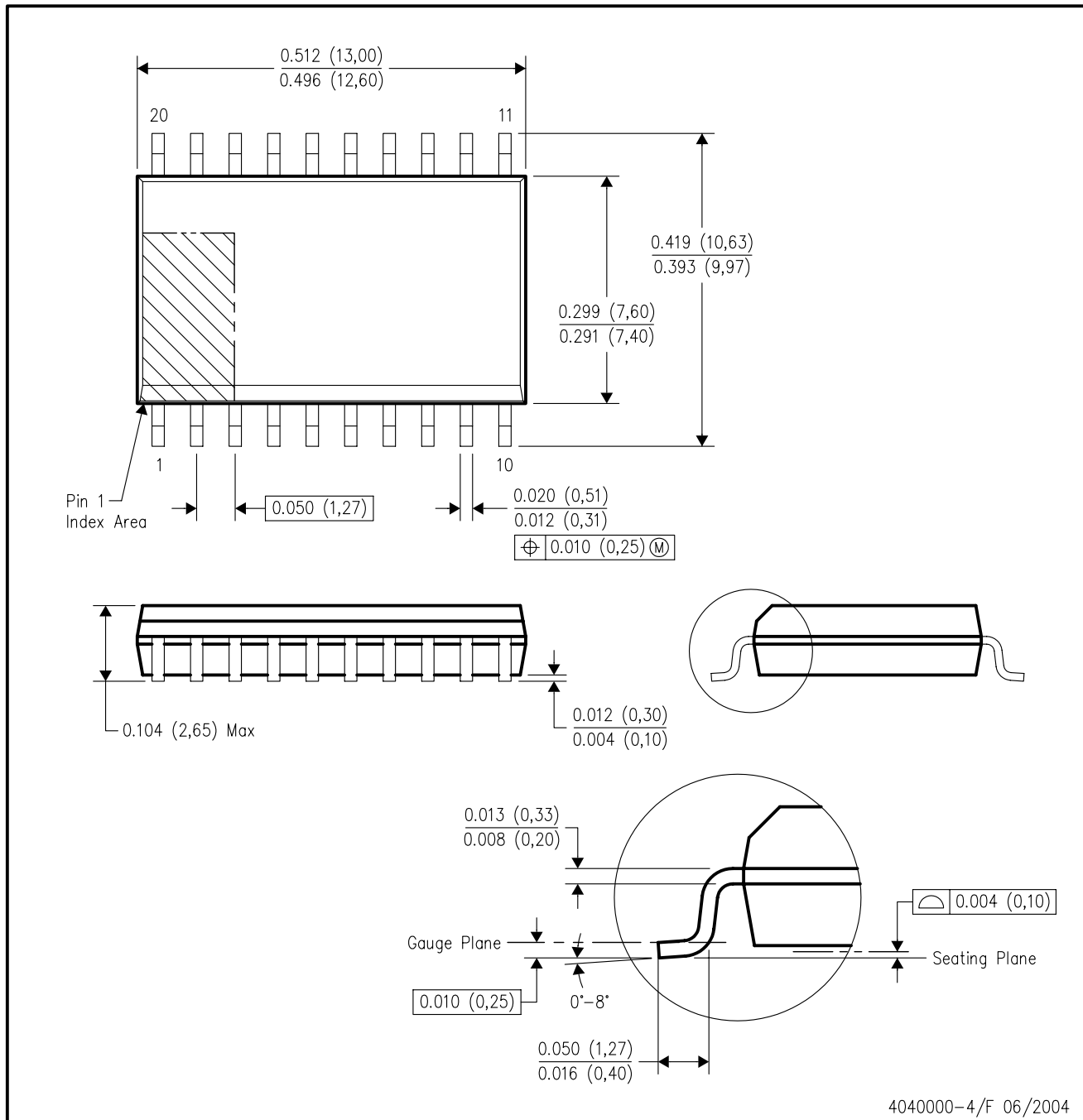
24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

DW (R-PDSO-G20)

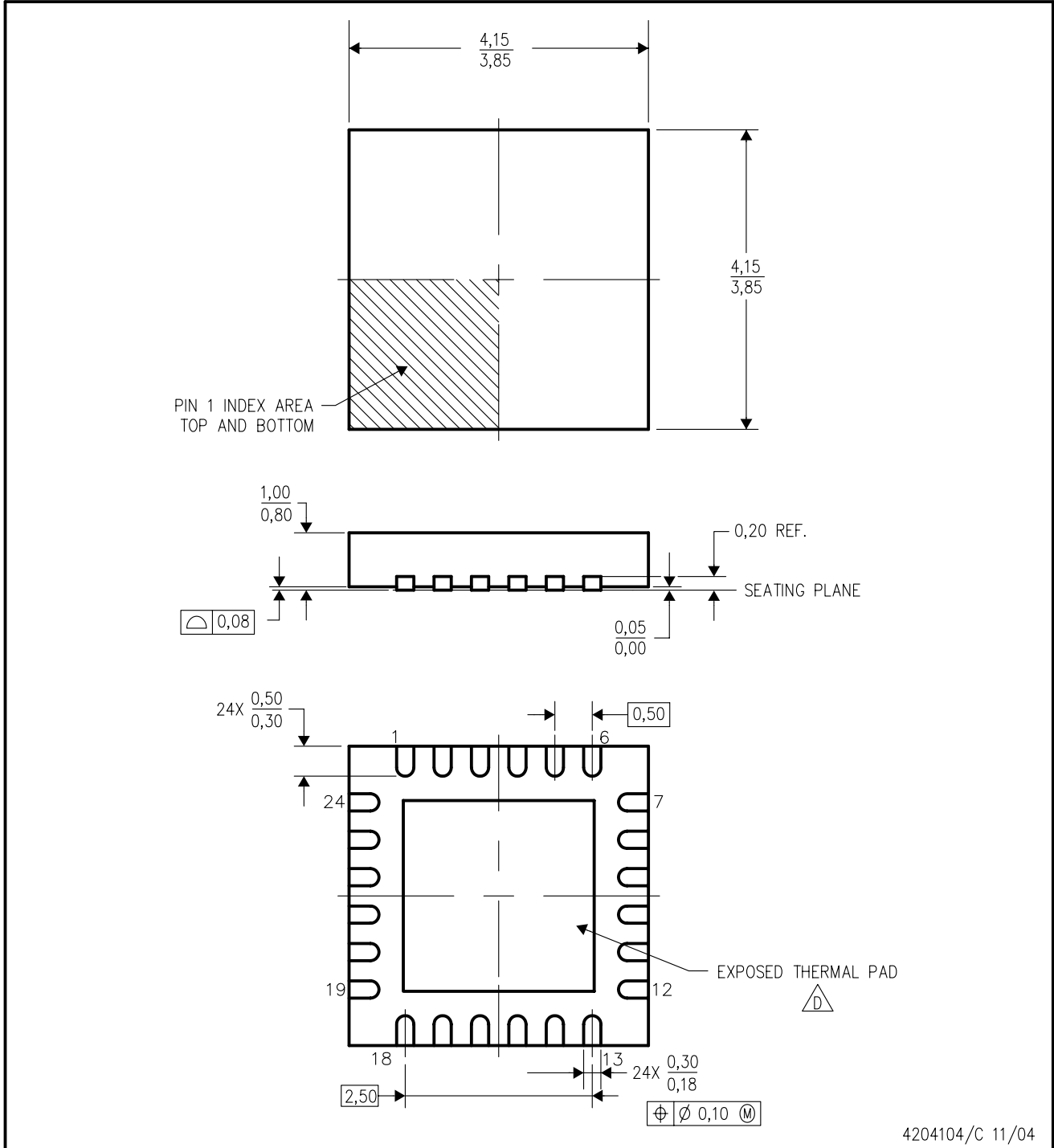
PLASTIC SMALL-OUTLINE PACKAGE




- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-013 variation AC.

RGE (S-PQFP-N24)

PLASTIC QUAD FLATPACK



4204104/C 11/04

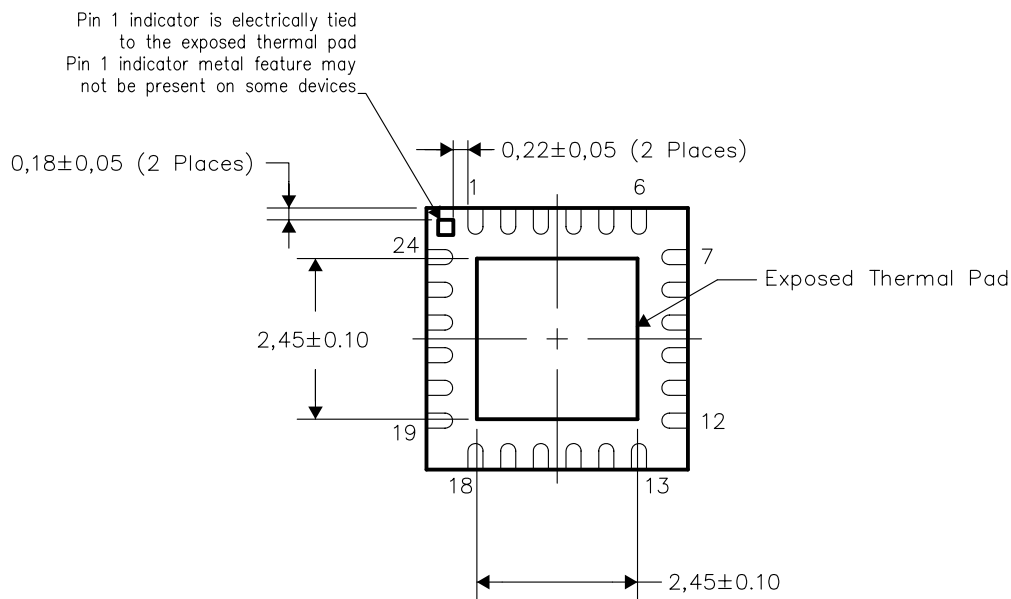
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Quad Flatpack, No-Leads (QFN) package configuration.
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THERMAL INFORMATION

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For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No-Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



4040064/F 01/97

- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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